



**Power Semiconductors
Power Modules &
RF Power MOSFETS
2008**



About Microsemi

Microsemi Power Products Group was created in 2006 with the acquisition of Advanced Power Technology, Inc., a company at the forefront of power semiconductor technology since its founding in 1984.

Our focus is on high voltage, high power and high performance applications. Our commitment is to maintain and enhance this position as a technological leader in MOS controlled devices and Diodes and to deliver products which contribute to our customers' success in delivering higher performance power systems.

Service... Outstanding technology is only part of the story. A global network of stocking distributors, representatives, applications engineers, and web tools are in place to support all phases of your product design, evaluation and procurement activities. In a world which demands superior execution, we've won numerous awards as a service leader.

Quality... Our commitment is to excellence in all things we do. Whether you are evaluating the quality of our products, our technical assistance, our customer service or the quality of our internal communications systems, excellence is our standard. Continuous improvement is fundamental to our business!

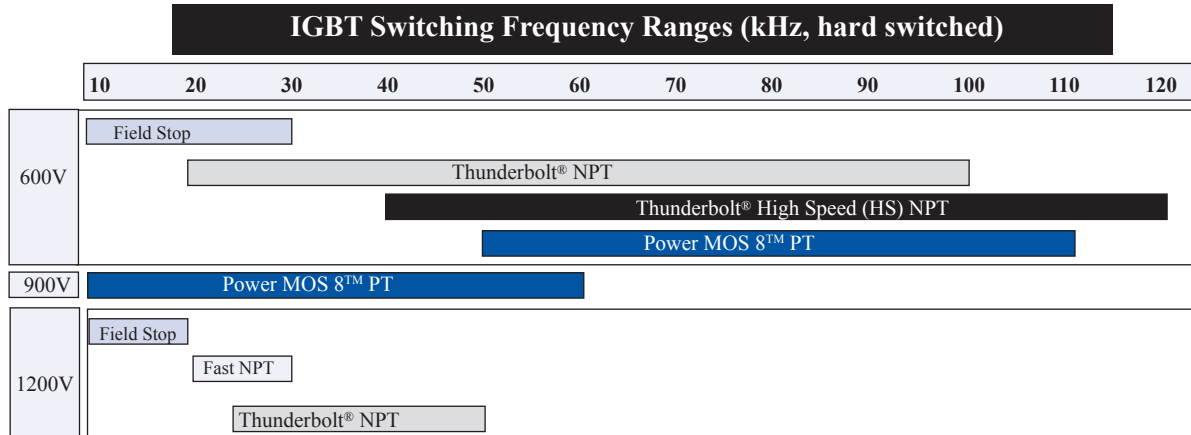
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Insulated Gate Bipolar Transistors (IGBTs)

IGBTs from Microsemi Power Products Group (PPG)

IGBT products from Microsemi PPG provide high quality solutions for a wide range of high voltage, high power applications. The switching frequency range spans from DC for minimal conduction loss to over 100kHz for very high power density SMPS applications. The frequency range for each product type is shown in the graph below. Each IGBT product represents the latest in IGBT technology, providing the best possible performance/cost combination for the targeted application. There are five product series that utilize three different IGBT technologies: Non-Punch-Through (NPT), Punch-Through (PT) and Field Stop.



Standard Series	Voltage Ratings (V)	Technology	Easy to Parallel	Short Circuit SOA	Comment
Thunderbolt®	600, 1200	NPT	X	X	General purpose, high speed
Thunderbolt® High Speed	600	NPT	X	X	Highest speed
FAST	1200	NPT	X	X	General purpose, medium speed
MOS 8™	600, 900	PT			Highest efficiency
Field Stop Trench Gate	600, 1200	Field Stop	X	X	Lowest conduction loss

Product Options

All standard IGBT products are available as a single IGBT or as a Combi product packaged with an anti-parallel DQ series diode. Package options include TO-220, D³, TO-247, T-Max®, TO-264, 264-MAX™ and SOT-227. Customized products are available; contact the factory for details.

NEW!

Resonant Mode Combi

New in 2008 are Resonant Mode Combi products, which are high speed IGBTs packaged with a low VF anti-parallel DL series diode. These Combis are intended for use in resonant mode circuits, such as the phase shifted bridge, where fast turn-off of the IGBT is needed but the recovery speed of the anti-parallel diode is less important than its forward voltage. Resonant Mode IGBTs maximize efficiency by reducing turn-off switching loss in the IGBT and minimizing conduction loss of the anti-parallel diode. The table below summarizes the key features and technology for the Resonant Mode IGBT products.

Resonant Mode Series	Voltage Ratings (V)	Technology	Easy to Parallel	Short Circuit SOA	Comment
Thunderbolt®	600, 1200	NPT	X	X	General purpose, high speed
Thunderbolt® High Speed	600	NPT	X	X	Highest speed
MOS 7	600	PT			Highest efficiency

Insulated Gate Bipolar Transistors (IGBTs)

NEW!

POWER MOS 8™

- PT Technology
- Fast Switching
- Highest Efficiency
- Combi with High Speed DQ Diode

FIELD STOP

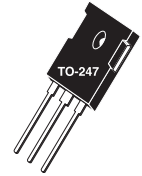
- Trench Technology
- Short Circuit Rated
- Lowest Conduction Loss
- Easy Paralleling
- Combi with High Speed DQ Diode

BV _{CES} Volts	V _{CE(ON)} Typ 25°C	I _{C2} 100°C	Recommended Maximum I _C		Part Number	Package Style
SINGLE						
600	2.0	28	50 kHz	80 kHz	APT28GA60K	TO-220
			19	14	APT36GA60B	TO-247 or D ³
			21	17	APT44GA60B	TO-247 or D ³
			26	20	APT54GA60B	TO-247 or D ³
			30	23	APT68GA60B	TO-247 or D ³
			35	27	APT80GA60B	TO-247 or D ³
			40	31	APT102GA60B2	T-MAX® or TO-264
900	2.0	102	25 kHz	50 kHz	APT27GA90K	TO-220
			14	8	APT35GA90B	TO-247 or D ³
			17	10	APT43GA90B	TO-247 or D ³
			21	13	APT64GA90B	TO-247 or D ³
			29	19	APT80GA90B	TO-247 or D ³
34	23					
Combi (IGBT & "DQ" FRED)						
600	2.0	28	50 kHz	80 kHz	APT28GA60BD15	TO-247 or D ³
			19	14	APT36GA60BD15	TO-247 or D ³
			21	17	APT44GA60BD30	TO-247 or D ³
			26	20	APT47GA60JD40	ISOTOP®
			30	23	APT54GA60BD30	TO-247 or D ³
			35	27	APT60GA60JD60	ISOTOP®
			40	31	APT68GA60LD40	TO-264
900	2.5	27	25 kHz	50 kHz	APT27GA90BD15	TO-247 or D ³
			14	8	APT35GA90BD15	TO-247 or D ³
			17	10	APT43GA90BD30	TO-247 or D ³
			21	13	APT46GA90JD40	ISOTOP®
			25	19	APT64GA90LD30	TO-264
34	23	APT80GA90LD40	TO-264			
SINGLE						
600	1.5	20	15 kHz	30 kHz	APT20GN60KG	TO-220
			15	10	APT20GN60BG	TO-247 or D ³
			15	10	APT30GN60KG	TO-220
			20	14	APT30GN60BG	TO-247 or D ³
			20	14	APT50GN60BG	TO-247 or D ³
			30	21	APT75GN60BG	TO-247 or D ³
			42	30	APT150GN60J	ISOTOP®
			75	47	APT100GN60B2G	T-MAX®
			54	39	APT150GN60B2G	T-MAX®
			79	57	APT200GN60B2G	T-MAX®
1200	1.7	22	10 kHz	20 kHz	APT15GN120KG	TO-220
			14	10	APT25GN120BG	TO-247 or D ³
			19	13	APT35GN120BG	TO-247 or D ³
			24	17	APT75GN120J	ISOTOP®
			36	22	APT50GN120B2G	T-MAX®
			32	22	APT100GN120J	ISOTOP®
			44	27	APT75GN120B2G	T-MAX® or TO-264
			45	30	APT100GN120B2G	T-MAX®
600	1.5	24	15 kHz	30 kHz	APT20GN60BDQ1G	TO-247 or D ³
			15	10	APT30GN60BDQ2G	TO-247 or D ³
			20	14	APT50GN60BDQ2G	TO-247 or D ³
			30	21	APT75GN60LDQ3G	TO-264
			42	30	APT150GN60JDQ4	ISOTOP®
			75	47	APT100GN60LDQ4G	TO-264
			54	39	APT150GN60LDQ4G	TO-264
			79	57	APT200GN60JDQ4	ISOTOP®
1200	1.7	22	10 kHz	20 kHz	APT15GN120BDQ1G	TO-247 or D ³
			14	10	APT25GN120B2DQ2G	T-MAX®
			19	13	APT35GN120L2DQ2G	264-MAX™
			24	17	APT75GN120JDQ3	ISOTOP®
			36	22	APT50GN120L2DQ2G	264-MAX™
			32	22	APT100GN120JDQ4	ISOTOP®
			44	27	APT100GN120JDQ4	ISOTOP®
			45	30	APT150GN120JDQ4	ISOTOP®

Current @ Frequency Test Conditions: T_j = 125°C, T_c = 100°C except Isotop® where T_c = 80°C, V_{cc} = 67% rated voltage Hard Switch



TO-220[K]

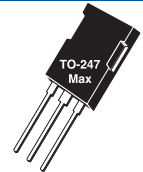


TO-247[B]

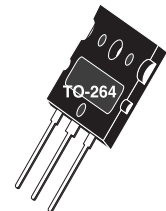


D³ PAK[S]

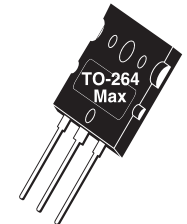
Part Numbers for D³ packages - replace "B" with "S" in part number



T-MAX®[B2]



TO-264[L]



264-MAX™[L2]

Part Numbers for TO-264 packages - replace "B2" with "L" in part number



ISOTOP®[J]
SOT-227

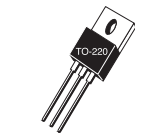


Insulated Gate Bipolar Transistors (IGBTs)

THUNDERBOLT®

- NPT Technology
- Short Circuit Rated
- Moderate to High Frequency
- Easy Paralleling

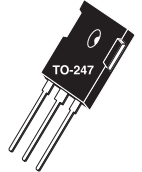
BV _{CES} Volts	V _{CE(ON)} Typ 25°C	I _{C2} 100°C	Recommended Maximum I _C		Part Number	Package Style
			30 kHz	60 kHz		
600	2.0	15	11	8	APT15GT60KRG	TO-220
			14	10	APT20GT60KRG	TO-220
		20	14	10	APT20GT60BRG	TO-247 or D ³
			19	13	APT30GT60KRG	TO-220
		30	19	13	APT30GT60BRG	TO-247 or D ³
			25	16	APT40GT60BRG	TO-247 or D ³
		40	30	20	APT50GT60BRG	TO-247 or D ³
			35	22	APT60GT60BRG	TO-247 or D ³
		48	29	18	APT60GT60JR	ISOTOP®
			56	35	APT100GT60B2RG	T-MAX® or TO-264
100	56	33	APT200GT60JR	ISOTOP®		
			20 kHz	40 kHz		
1200	3.2	18	11	8	APT15GT120BRG	TO-247 or D ³
		25	16	11	APT25GT120BRG	TO-247 or D ³
		50	27	17	APT50GT120B2RG	T-MAX® or TO-264
		60	40	21	APT100GT120JR	ISOTOP®
		90	52	25	APT150GT120JR	ISOTOP®
Combi (IGBT & "DQ" FRED)			30 kHz	60 kHz		
600	2.0	15	11	8	APT15GT60BRDQ1G	TO-247 or D ³
			14	10	APT20GT60BRDQ1G	TO-247 or D ³
		30	19	13	APT30GT60BRDQ2G	TO-247 or D ³
			29	18	APT60GT60JRDQ3	ISOTOP®
		50	30	20	APT50GT60BRDQ2G	TO-247 or D ³
			37	22	APT100GT60JRDQ4	ISOTOP®
		100	56	35	APT200GT60JRDQ4	ISOTOP®
		20 kHz	40 kHz			
1200	3.2	18	11	8	APT15GT120BRDQ1G	TO-247 or D ³
		25	16	11	APT25GT120BRDQ2G	TO-247 or D ³
		50	27	17	APT50GT120B2RDQ2G	T-MAX® or TO-264
		42	34	19	APT75GT120JRDQ3	ISOTOP®
		60	40	21	APT100GT120JRDQ4	ISOTOP®
					50 kHz	80 kHz
600	2.8	20	9	5	APT20GS60KRG	TO-220
			14	9	APT30GS60KRG	TO-220
			23	16	APT50GS60BRG	TO-247 or D ³
					50 kHz	80 kHz
600	2.8	20	9	5	APT20GS60BRDQ1G	TO-247 or D ³
			14	9	APT30GS60BRDQ2G	TO-247 or D ³
			23	16	APT50GS60BRDQ2G	TO-247 or D ³
FAST			15 kHz	30 kHz		
1200	2.5	14	8	5	APT11GF120KRG	TO-220
			11	7	APT20GF120KRG	TO-220
		20	11	7	APT20GF120BRG	TO-247 or D ³
			16	10	APT33GF120BRG	TO-247 or D ³
		75	27	17	APT50GF120B2RG	T-MAX®
			27	17	APT50GF120LRG	TO-264
Combi (IGBT & "DQ" FRED)			15 kHz	30 kHz		
1200	2.5	14	8	5	APT11GF120BRDQ1G	TO-247 or D ³
			11	7	APT20GF120BRDQ1G	TO-247 or D ³
		35	16	10	APT33GF120B2RDQ2G	T-MAX®
			16	10	APT33GF120LRDQ2G	TO-264
		42	24	15	APT40GF120JRDQ2	ISOTOP®
			33	17	APT50GF120JRDQ3	ISOTOP®
		80	42	20	APT60GF120JRDQ3	ISOTOP®
Combi (IGBT & "DL" FRED)			50 kHz	80 kHz		
600	2.8	50	23	16	APT50GS60BRDLG	TO-247
			14	9	APT30GS60BRDLG	TO-247
		30	41	31	APT50GP60LDLG	TO-264
			28	22	APT30GP60B2DLG	T-MAX® or TO-264
		25	17	14	APT15GP60BDLG	TO-247
					30 kHz	60 kHz
1200	2.0	200	56	33	APT200GT60JRDL	ISOTOP®
			56	35	APT100GT60JRDL	ISOTOP®
		100	30	20	APT50GT60BRDLG	TO-247
			14	10	APT30GT60BRDLG	TO-247
		30			20 kHz	40 kHz
25	16		11	APT25GT120BRDLG	TO-247	
	28		17	APT50GT120B2RDLG	T-MAX®	
100	40	21	APT100GT120JRDL	ISOTOP®		



TO-220[K]

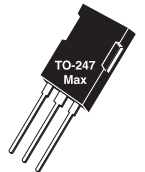


D³ PAK[S]

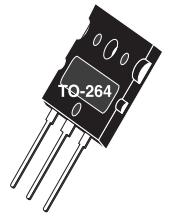


TO-247[B]

Part Numbers for D³ packages - replace "B" with "S" in part number

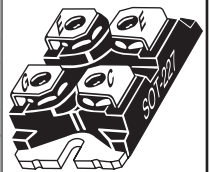


T-MAX®[B2]

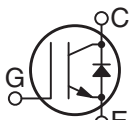


TO-264[L]

Part Numbers for L packages - replace "B2" with "L" in part number



ISOTOP®[J]
SOT-227



Current @ Frequency Test Conditions: T_j = 125°C, T_c = 100°C except Isotop® where T_c = 80°C, V_{cc} = 67% rated voltage Hard Switch

THUNDERBOLT® HIGH SPEED

- High Speed Switching - Reduced E_{off}
- Fastest Switching
- NPT Technology

FAST

- NPT Technology
- Short Circuit Rated
- Low to Moderate Frequency
- Low Conduction Loss
- Easy Paralleling

NEW!

RESONANT MODE COMBI IGBTs

- NPT Technology
- PT Technology
- Low V_F Diode
- Ultrasoft Recovery Diode
- "GT" and "GS" Avalanche Rated
- High Speed Switching - Reduced E_{off}

NEW Power MOS 8™ MOSFETs / FREDFETs (fast body diode)



Power MOS 8™ is a new family of high speed, high voltage (500-1200V) N-channel switch-mode power transistors with lower EMI characteristics and lower cost compared to previous generation devices. These new MOSFETs /FREDFETs have been optimized for both hard and soft switching in high frequency, high voltage applications rated above 500W. There are 3 product types in the Power MOS 8™ MOSFET family:



- 1) **MOSFET**
- 2) **FREDFETs** have a fast recovery body diode characteristic, providing high commutation dv/dt ruggedness and high reliability in ZVS circuits.
- 3) **Ultrafast Recovery FREDFETs** have even faster recovery of the body diode for superior reliability in ZVS circuits.

Features

- Fast switching
- Low EMI
- Quiet switching
- Avalanche energy rated
- Low gate charge
- Lower cost

Applications

- Power factor correction
 - Server and telecom power systems
 - Solar inverters
 - Arc welding
 - Plasma cutting
 - Battery chargers
 - Medical
 - Semiconductor capital equipment
 - Induction heating
-


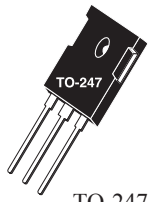

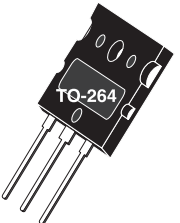
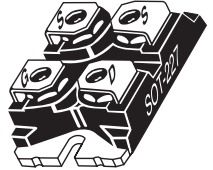
Quiet Switching

The new Power MOS 8™ series is a result of extensive research into quiet switching. Input and reverse transfer capacitance values as well as their ratio were set at specific values to achieve quiet switching with minimal switching loss. The Power MOS 8™ series of devices are inherently quiet switching, stable when connected in parallel, very efficient, and lower cost than previous generations.

Body Diode Options



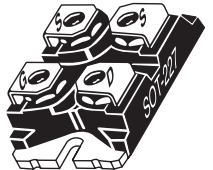
As with previous generation products, Power MOS 8™ MOSFETs and FREDFETs are available in all voltage ratings. A FREDFET is a MOSFET with a faster recovery intrinsic body diode. New with Power MOS 8™ are Ultrafast Recovery FREDFET products, available in 500V and 600V ratings. The Ultrafast Recovery FREDFET has even faster body diode recovery speed. This results in improved reliability in ZVS circuits due to shorter minority carrier lifetime and increased commutation dv/dt ruggedness. There is a slight $R_{DS(on)}$ increase with the Ultrafast Recovery FREDFET. In some cases there is a choice of FREDFET or Ultrafast Recovery FREDFET to meet your cost/reliability requirements. If a fast recovery body diode is not needed, MOSFET versions are available.

Power MOS 8™ MOSFETs / FREDFETs

$BV_{(DSS)}$ Volts	$R_{DS(ON)}$ Max	I_D	MOSFET Part #	I_D	FREDFET Part #	Package Style		
1200	4.00	4	APT4M120K			TO-220	 TO-220[K]	
	4.60			4	APT4F120K	TO-220		
	2.90			7	APT7F120B	TO-247 or D ³	 TO-247[B]	
	2.50	7	APT7M120B			TO-247 or D ³		
	1.40			13	APT13F120B	TO-247 or D ³		
	1.20	14	APT14M120B			TO-247 or D ³		
	0.80			22	APT22F120B2	T-MAX® or TO-264		
	0.68	24	APT24M120B2			T-MAX® or TO-264		
	0.65			26	APT26F120B2	T-MAX® or TO-264		
	0.65			17	APT17F120J	ISOTOP®		
	0.56	28	APT28M120B2			T-MAX® or TO-264		
	0.56	19	APT19M120J	17				
	0.35			32	APT32F120J	ISOTOP®		
0.30	34	APT34M120J			ISOTOP®	 D ³ PAK[S]		
1000	2.90			5	APT5F100K		TO-220	Part Numbers for D ³ packages - replace "B" with "S" in part number
	2.50	6	APT6M100K			TO-220		
	2.00			7	APT7F100B	TO-247		
	1.80	8	APT8M100B			TO-247 or D ³		
	1.70			9	APT9F100B	TO-247 or D ³		
	1.50	9	APT9M100B			TO-247 or D ³		
	1.00			14	APT14F100B	TO-247 or D ³		
	0.90	14	APT14M100B			TO-247 or D ³		
	0.80			17	APT17F100B	TO-247 or D ³		
	0.70	18	APT18M100B			TO-247 or D ³		
	0.46			29	APT29F100B2	T-MAX® or TO-264		
	0.46			19	APT19F100J	ISOTOP®		
	0.40	31	APT31M100B2	34	APT34F100B2	T-MAX® or TO-264		
	0.40	21	APT21M100J	22	APT22F100J	ISOTOP®		
	0.33	37	APT37M100B2			T-MAX® or TO-264		
	0.33	25	APT25M100J			ISOTOP®		
	800	0.21			41	APT41F100J	ISOTOP®	
0.18		45	APT45M100J			ISOTOP®		
800		1.70			7	APT7F80K	TO-220	 TO-264[L]
		1.50	8	APT8M80K			TO-220	
		1.00			11	APT11F80B	TO-247 or D ³	Part Numbers for TO-264 packages - replace "B2" with "L" in part number
		0.90	12	APT12M80B			TO-247 or D ³	
		0.65			17	APT17F80B	TO-247 or D ³	
		0.56	18	APT18M80B			TO-247 or D ³	
		0.50			22	APT22F80B	TO-247 or D ³	
		0.43	24	APT24M80B			TO-247 or D ³	
		0.28			38	APT38F80B2	T-MAX® or TO-264	
		0.24	41	APT41M80B2	44	APT44F80B2	T-MAX® or TO-264	
		0.24			29	APT29F80J	ISOTOP®	
		0.21	48	APT48M80B2			T-MAX® or TO-264	
		0.21	32	APT32M80J			ISOTOP®	
	0.13			53	APT53F80J	ISOTOP®		
0.11	58	APT58M80J			ISOTOP®	 ISOTOP®[J] SOT-227 (ISOLATED BASE)		

Power MOS 8TM MOSFETs / FREDFETs

Ultrafast Recovery FREDFETs have even faster recovery of the body diode for superior reliability in ZVS circuits

BV _(DSS) Volts	R _{DS(ON)} Max	I _D	MOSFET Part #	I _D	FREDFET Part #	I _D	Ultrafast Recovery FREDFET Part#	Package	
600	0.62			12	APT12F60K			TO-220	 TO-220[K]
	0.48			15	APT15F60B			TO-247 or D ³	
	0.42						18	APT18H60B	TO-247 or D ³
	0.39				18	APT18F60B			TO-247 or D ³
	0.31				23	APT23F60B			TO-247 or D ³
	0.25				28	APT28F60B			TO-247 or D ³
	0.23						33	APT33H60B	TO-247 or D ³
	0.21	34	APT34M60B	34	APT34F60B				TO-247 or D ³
	0.16	43	APT43M60B2	43	APT43F60B2				T-MAX® or TO-264
	0.16	30	APT30M60J	30	APT30F60J				ISOTOP®
	0.13	56	APT56M60B2	56	APT56F60B2				T-MAX® or TO-264
	0.13	39	APT39M60J	39	APT39F60J				ISOTOP®
	0.11						63	APT63H60B2	T-MAX® or TO-264
	0.11						44	APT44H60J	ISOTOP®
	0.10	66	APT66M60B2						T-MAX® or TO-264
	0.10	47	APT47M60J						ISOTOP®
0.065						77	APT77H60J	ISOTOP®	
0.060	80	APT80M60J						ISOTOP®	
500	0.39			15	APT15F50K			TO-220	 T-MAX®[B2]
	0.30			20	APT20F50B			TO-247 or D ³	
	0.26						23	APT23H50B	TO-247 or D ³
	0.24				24	APT24F50B			TO-247 or D ³
	0.19				30	APT30F50B			TO-247 or D ³
	0.15				37	APT37F50B	41	APT41H50B	TO-247 or D ³
	0.14				42	APT42F50B			TO-247 or D ³
	0.10	56	APT56M50B2	56	APT56F50B2				T-MAX® or TO-264
	0.10	38	APT38M50J	38	APT38F50J				ISOTOP®
	0.075	75	APT75M50B2	75	APT75F50B2				T-MAX® or TO-264
	0.075	51	APT51M50J	51	APT51F50J				ISOTOP®
	0.070						81	APT81H50B2	T-MAX® or TO-264
	0.070						56	APT56H50J	ISOTOP®
	0.065	84	APT84M50B2						T-MAX® or TO-264
	0.065	58	APT58M50J						ISOTOP®
	0.041						97	APT97H50J	ISOTOP®
0.038	100	APT100M50J						ISOTOP®	
0.107						54	APT54H50B2	T-MAX® or TO-264	
Low Voltage Power MOS V[®] MOSFETs / FREDFETs									 ISOTOP®[J] SOT-227 (ISOLATED BASE)
300	0.085	40	APT30M85BVFRG	40	APT30M85BVFRG			TO-247 or D ³	
	0.070	48	APT30M70BVFRG	48	APT30M70BVFRG			TO-247 or D ³	
	0.040	70	APT30M40JVFRG	70	APT30M40JVFRG			ISOTOP®	
	0.019	130	APT30M19JVFR	130	APT30M19JVFR			ISOTOP®	
200	0.045	56	APT20M45BVFRG	56	APT20M45BVFRG			TO-247 or D ³	
	0.038	67	APT20M38BVFRG	37	APT20M38BVFRG			TO-247 or D ³	
	0.022	100	APT20M22B2VFRG	100	APT20M22B2VFRG			T-MAX® or TO-264	
	0.011	175	APT20M11JVFR	175	APT20M11JVFR			ISOTOP®	

Part Numbers for D³ packages - replace "B" with "S" in part number

Part Numbers for TO-264 packages - replace "B2" with "L" in part number

For additional Ultrafast Recovery FREDFET part numbers contact the factory.

All Products RoHS Compliant

Ultrafast, Low Gate Charge MOSFETs

FOR 250 kHz - 2 MHz SWITCHING APPLICATIONS

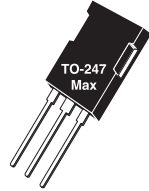
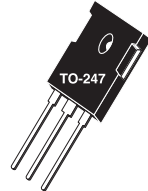
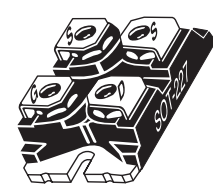
The Ultrafast, Low Gate Charge MOSFET family combines the lowest gate charge available in the industry with Microsemi's proprietary self-aligned aluminum metal gate structure. The result is a MOSFET capable of extremely fast switching speeds and very low switching losses. The metal gate structure and the layout of these chips provide an internal series gate resistance (EGR) an order of magnitude lower than competitive devices built with a polysilicon gate.

These devices are ideally suited for high frequency and pulsed high voltage applications.


Typical Applications:


- Class D amplifiers up to 2 MHz
- High voltage pulsed DC
- AM transmitters
- Plasma deposition/etch

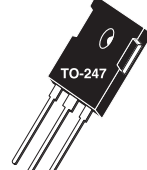
FEATURES:	BENEFITS:
<ul style="list-style-type: none"> • Series Gate Resistance (Rg) <0.1 ohm 	<ul style="list-style-type: none"> • Fast switching uniform signal propagation
<ul style="list-style-type: none"> • Tr and Tf times of <10ns 	<ul style="list-style-type: none"> • Pulse power applications
<ul style="list-style-type: none"> • Industry's Lowest Gate Charge 	<ul style="list-style-type: none"> • Fast switching, reduced gate drive power


BV _(DSS) Volts	R _{DS(ON)} Max	I _D	MOSFET Part #	Package Style	
1200	0.670	18	APT12067B2LLG	T-MAX®	 T-MAX®[B2]
	0.670	17	APT12067JLL	ISOTOP®	
	0.570	22	APT12057B2LLG	T-MAX®	
	0.570	19	APT12057JLL	ISOTOP®	
	0.310	30	APT12031JLL	ISOTOP®	
1000	0.450	23	APT10045B2LLG	T-MAX®	 TO-247[B]
	0.450	21	APT10045JLL	ISOTOP®	
	0.350	28	APT10035B2LL	T-MAX®	
	0.350	25	APT10035JLL	ISOTOP®	
800	0.240	31	APT8024B2LL	T-MAX®	 ISOTOP®[J] SOT-227 (ISOLATED BASE)
	0.24	29	APT8024JLL	ISOTOP®	
	0.200	38	APT8020B2LL	T-MAX®	
	0.200	33	APT8020JLL	ISOTOP®	
	0.140	42	APT8014JLL	ISOTOP®	
500	0.240	22	APT5024BLLG	TO-247	
	0.180	27	APT5018BLLG	TO-247	
	0.140	35	APT5014BLLG	TO-247	
	0.100	46	APT5010B2LLG	T-MAX®	
	0.075	57	APT50M75B2LLG	T-MAX®	
	0.050	71	APT50M50JLL	ISOTOP®	
	0.038	88	APT50M38JLL	ISOTOP®	

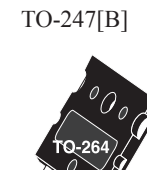
BV _{DSS} Volts	R _{DS(ON)} Ohms	I _{D(Cont)} Amps	Part Number	Package Style	
C3 TECHNOLOGY					
800	0.450	11	APT11N80KC3G	TO-220	
	0.450	11	APT11N80BC3G	TO-247	
	0.145	34	APT34N80B2C3G	T-MAX®	
	0.145	34	APT34N80LC3G	TO-264	
	0.145	31	APT31N80JC3	ISOTOP®	
600	0.070	47	APT47N60BC3G	TO-247	
	0.070	47	APT47N60SC3G	D ³	
	0.035	77	APT77N60JC3	ISOTOP®	
COOLMOS FREDFETS					
600	0.083	40	APT47N60BCFG	TO-247	
	0.078	62	APT62N60JCF	ISOTOP®	
	SERVER SERIES				
	0.045	60	APT60N60BCSG	TO-247	
	0.042	94	APT94N60L2C3G	264-MAX™	
	0.023	82	APT82N60JCS	ISOTOP®	



TO-220[K]

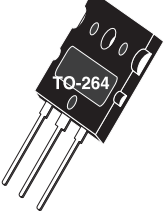

D³ PAK[S]
TO-268

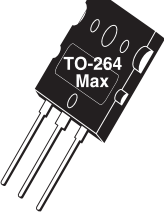

TO-247

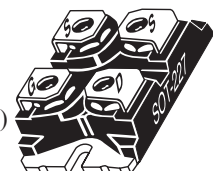

TO-247
Max


TO-247[B]


T-MAX®[B2]


TO-264[L]


264-MAX™ [L2]


ISOTOP®[J]
SOT-227
(ISOLATED BASE)

“COOLMOS” comprise a new family of transistors developed by Infineon Technologies AG.
“COOLMOS” is a trademark of Infineon Technologies AG

Linear MOSFETs

What is a Linear MOSFET?

A MOSFET specifically designed to be more robust than a standard MOSFET when operated with both high voltage and high current near DC conditions (>100msecs).

The Problem with SMPS MOSFETs

MOSFETs optimized for high frequency SMPS applications have poor high voltage DC SOA. Most SMPS type MOSFETs over-state SOA capability at high voltage on the data sheets. Above ~30V and DC conditions, SOA drops faster than is indicated by P_D limited operation.

For pulsed loads (t<10ms) there is generally no problem using a standard MOSFET.

Technology Innovation


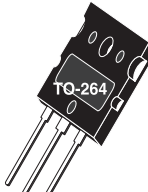
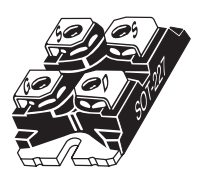
Introduced in 1999, Microsemi modified its proprietary patented self-aligned metal gate MOSFET technology for enhanced performance in high voltage, linear applications. These Linear MOSFETs typically provide 1.5-2.0 times the DC SOA capability at high voltage compared to other MOSFET technologies optimized for switching applications.

Designers will need Linear MOSFETs when...

- High Current & > 200V >100msec
- Used as a variable power resistor
- Soft start application (limit surge currents)
- Linear amplifier circuit

Typical Applications...

- Active loads above 200 volts such as DC dynamic loads for testing power supplies, batteries, fuel cells, etc.
- High voltage, high current constant current sources.

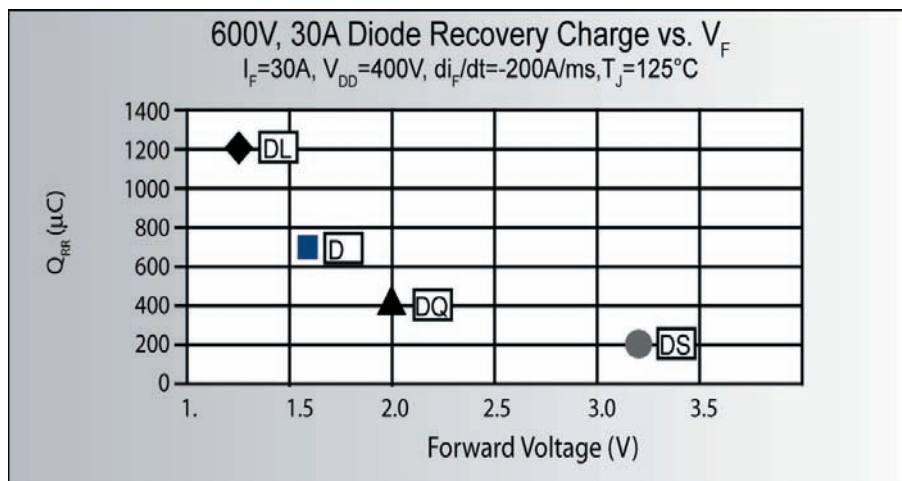
BV _{DSS} Volts	R _{DS(ON)} Ohms	I _{D(Cont)} Amps	SOA Watts	Part Number	Package Style
1000	0.600	18	325	APL1001J	 T-MAX®[B2]  TO-264[L]  ISOTOP®[J] SOT-227 (ISOLATED BASE)
600	0.125	49	325	APL602B2G	
	0.125	43	325	APL602J	
500	0.090	58	325	APL502B2G	
	0.090	52	325	APL502J	

Part Numbers for TO-264 packages - replace "B2" with "L" in part number

Microsemi PPG offers five series of discrete diode products: a new **DL** series low V_F ultra-soft recovery, the medium speed medium V_F **D** series, the high speed **DQ** series, the very high speed **DS** series, and the silicon Schottky **S** series. These series of diodes are designed to provide high quality solutions to a wide range of high voltage, high power application requirements, ranging from fast recovery for continuous conduction mode power factor correction to low conduction loss for output rectification. Distinguishing features, technology used, and applications for each product family are summarized in the table below.

Series	Voltage Ratings	Features	Applications	Comment
NEW! DL	600	Low V_F Ultra-soft recovery Avalanche Rated	Output rectifier Resonant circuits	Ultra-soft recovery minimizes or eliminates snubber
D	200, 300, 400, 600, 1000, 1200	Medium V_F Medium Speed	Freewheeling Diode Output rectifier DC-DC converter	Proprietary platinum process
DQ	600, 1000, 1200	High speed Avalanche Rated	PFC Freewheeling Diode DC-DC converter	Stepped epi improves softness Proprietary platinum process
DS	600	Very high speed	High frequency PFC	Proprietary platinum process
Schottky	200	Low V_F Avalanche rated	Output rectifier Freewheeling Diode DC-DC converter	

The graph below shows the relative recovery speed and forward voltage positions of 600V DL, D, DQ and DS series diodes.



Ultra Fast Recovery Diodes

NEW - "DL" DIODES

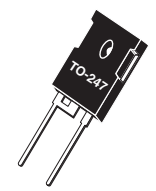
Volts	$I_{F(avg)}$ Amps	V_F (volts) Typ 25°C	t_{RR} (ns) Typ 25°C	Q_{RR} (nC) Typ 125°C at $I_F = I_F(avg)$	Diode Series	Part Number	Package Style
SINGLE							
1200	15	2.8	21	960	DQ	APT15DQ120BG	TO-247
	15	2.8	21	960	DQ	APT15DQ120KG	TO-220
	15	2.0	32	1300	D	APT15D120BG	TO-247
	15	2.0	32	1300	D	APT15D120KG	TO-220
	30	2.8	24	1800	DQ	APT30DQ120BG	TO-247
	30	2.8	24	1800	DQ	APT30DQ120KG	TO-220
	30	2.0	31	3450	D	APT30D120BG	TO-247
	40	2.8	26	2200	DQ	APT40DQ120BG	TO-247
	60	2.8	30	2800	DQ	APT60DQ120BG	TO-247
	60	2.0	38	4000	D	APT60D120BG	TO-247
	75	2.8	32	3340	DQ	APT75DQ120BG	TO-247
1000	15	2.5	20	810	DQ	APT15DQ100BG	TO-247
	15	2.5	20	810	DQ	APT15DQ100KG	TO-220
	15	1.9	28	1550	D	APT15D100KG	TO-220
	30	2.5	22	1250	DQ	APT30DQ100BG	TO-247
	30	2.5	22	1250	DQ	APT30DQ100KG	TO-247
	30	1.9	29	2350	D	APT30D100BG	TO-247
	40	2.5	24	1430	DQ	APT40DQ100BG	TO-247
	60	2.5	29	2325	DQ	APT60DQ100BG	TO-247
	60	1.9	34	3600	D	APT60D100BG	TO-247
	75	2.5	33	2660	DQ	APT75DQ100BG	TO-247
600	8	2.0	14	160	DQ	APT8DQ60KG	TO-220
	15	2.0	16	250	DQ	APT15DQ60BG	TO-247
	15	2.0	16	250	DQ	APT15DQ60KG	TO-220
	15	1.6	21	520	D	APT15D60BG	TO-247
	15	1.6	21	520	D	APT15D60KG	TO-220
	30	2.0	19	400	DQ	APT30DQ60BG	TO-247
	30	2.0	19	400	DQ	APT30DQ60KG	TO-220
	30	1.6	23	700	D	APT30D60BG	TO-247
	30	1.25	35	3800	DL	APT30DL60BG	TO-247
	40	2.0	22	480	DQ	APT40DQ60BG	TO-247
	50	1.25	38	3800	DL	APT50DL60BG	TO-247
	60	2.0	26	640	DQ	APT60DQ60BG	TO-247
	60	1.6	40	920	D	APT60D60BG	TO-247
	75	2.0	29	650	DQ	APT75DQ60BG	TO-247
	75	1.25	42	3800	DL	APT75DL60BG	TO-247
100	1.25	45	3800	DL	APT100DL60BG	TO-247	
150	1.25	53	3800	DL	APT150DL60B2G	T-MAX®	
400	30	1.3	22	360	D	APT30D40BG	TO-247
	60	1.3	30	540	D	APT60D40BG	TO-247
200	15	0.80	20	440	Schottky	APT15S20KG	TO-220
	30	1.1	21	150	D	APT30D20BG	TO-247
	30	0.83	25	448	Schottky	APT30S20BG	TO-247
	60	1.1	30	250	D	APT60D20BG	TO-247
	60	0.83	35	490	Schottky	APT60S20BG	TO-247
	100	0.89	40	690	Schottky	APT100S20BG	TO-247
TANDEM, DS DIODES FOR PFC BOOST APPLICATIONS							
600	15	3.2	13	85	DS	APT15DS60BG	TO-247
	30	3.2	17	180	DS	APT30DS60BG	TO-247
<small>(2, 300V Diodes Connected In Series)</small>							



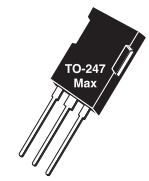
TO-220[K]



D³ PAK[S]
TO-268

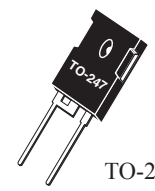


TO-247[B]



T-MAX®[B2]

Part Numbers for D³ packages - replace "B" with "S" in part number

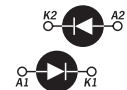


TO-247[B]

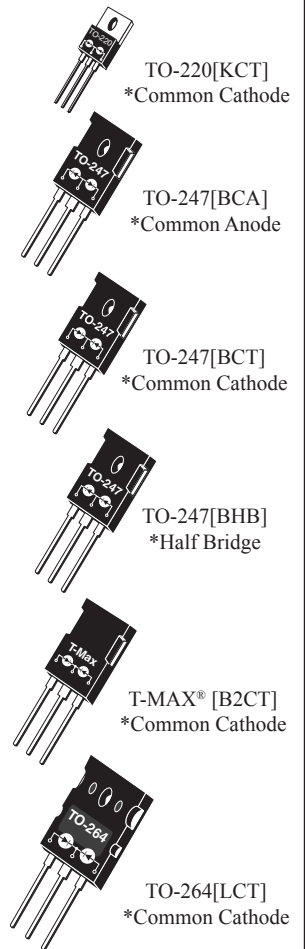
Volts	I _{F(av)} Amps	V _F (volts) Typ 25°C	t _{RR} (ns) Typ 25°C	Q _{RR} (nC) Typ 125°C at I _F = I _{F(av)}	Diode Series	Part Number	Package Style
1200	2x27	2.0	31	3450	D	APT2X30D120J	ISOTOP®
	2x30	2.6	25	1800	DQ	APT2X30DQ120J	
	2x53	2.0	38	4000	D	APT2X60D120J	
	2x60	2.5	30	2890	DQ	APT2X60DQ120J	
	2x93	2.0	47	5350	D	APT2X100D120J	
	2x100	2.4	45	5240	DQ	APT2X100DQ120J	
1000	2x28	1.9	29	2350	D	APT2X30D100J	
	2x55	1.9	34	3600	D	APT2X60D100J	
	2x60	2.2	30	2350	DQ	APT2X60DQ100J	
	2x95	1.9	43	4050	D	APT2X100D100J	
	2x100	2.1	45	3645	DQ	APT2X100DQ100J	
600	2x30	1.8	20	400	DQ	APT2X30DQ60J	
	2x30	1.6	23	700	D	APT2X30D60J	
	2x60	1.7	27	650	DQ	APT2X60DQ60J	
	2x60	1.6	40	920	D	APT2X60D60J	
	2x100	1.6	30	980	DQ	APT2X100DQ60J	
	2x100	1.6	34	1450	D	APT2X100D60J	
	2x150	1.25	53	3800	DL	APT2X150DL60J	
400	2x30	1.3	22	360	D	APT2X30D40J	
	2x60	1.3	30	540	D	APT2X60D40J	
	2x100	1.3	37	1050	D	APT2X100D40J	
200	2x30	0.80	25	448	Schottky	APT2X31S20J	
	2x60	0.83	35	490	Schottky	APT2X61S20J	
	2x100	1.1	39	840	D	APT2X100D20J	
	2x100	0.89	40	690	Schottky	APT2X101S20J	
1000	2x15	2.5	20	810	DQ	APT15DQ100BCTG	TO-247 [BCT]
	2x15	1.9	28	1550	D	APT15D100BHBG	TO-247 [BHB]
	2x30	2.5	22	1250	DQ	APT30DQ100BCTG	TO-247 [BCT]
	2x30	1.9	30	2350	D	APT30D100BHBG	TO-247 [BHB]
	2x30	1.9	30	2350	D	APT30D100BCAG	TO-247 [BCA]
	2x40	2.5	24	1430	DQ	APT40DQ100BCTG	TO-247 [BCT]
	2x60	2.5	29	2325	DQ	APT60DQ100LCTG	TO-264 [LCT]
	2x60	1.9	35	3600	D	APT60D100LCTG	TO-264 [LCT]
600	2x8	2.0	15	160	DQ	APT8DQ60KCTG	TO-220 [KCT]
	2x15	2.0	15	250	DQ	APT15DQ60BCTG	TO-247 [BCT]
	2x15	1.6	20	520	D	APT15D60BCAG	TO-247 [BCA]
	2x30	2.0	22	480	DQ	APT30DQ60BHBG	TO-247 [BHB]
	2x30	2.0	19	400	DQ	APT30DQ60BCTG	TO-247 [BCT]
	2x30	1.6	23	700	D	APT30D60BCTG	TO-247 [BCT]
	2x30	1.6	25	700	D	APT30D60BHBG	TO-247 [BHB]
	2x30	1.6	25	700	D	APT30D60BCAG	TO-247 [BCA]
	2x30	1.25	35	3800	DL	APT30DL60BCTG	TO-247 [BCT]
	2x40	2.0	22	480	DQ	APT40DQ60BCTG	TO-247 [BCT]
	2x50	1.25	38	3800	DL	APT50DL60BCTG	TO-247 [BCT]
	2x60	2.0	26	640	DQ	APT60DQ60BCTG	TO-247 [BCT]
	2x60	1.6	30	920	D	APT60D60LCTG	TO-264 [LCT]
400	2x60	1.3	30	540	D	APT60D40LCTG	TO-264 [LCT]
200	2x15	0.80	20	440	Schottky	APT15S20KCTG	TO-220 [KCT]
	2x15	0.80	20	440	Schottky	APT15S20BCTG	TO-247 [BCT]
	2x30	1.1	21	150	D	APT30D20BCAG	TO-247 [BCA]
	2x30	0.80	25	448	Schottky	APT30S20BCTG	TO-247 [BCT]
	2x60	1.1	30	250	D	APT60D20LCTG	TO-264 [LCT]
	2x60	0.83	35	490	Schottky	APT60S20B2CTG	T-MAX® [B2CT]
	2x100	0.89	40	690	Schottky	APT100S20LCTG	TO-264 [LCT]



ISOTOP®[J] SOT-227
Antiparallel
Configuration
(ISOLATED BASE)



Part Numbers for Parallel Configuration replace 30, 60, or 100 with 31, 61, or 101. Except Schottky
Example: 2X30D120J becomes 2X31D120J



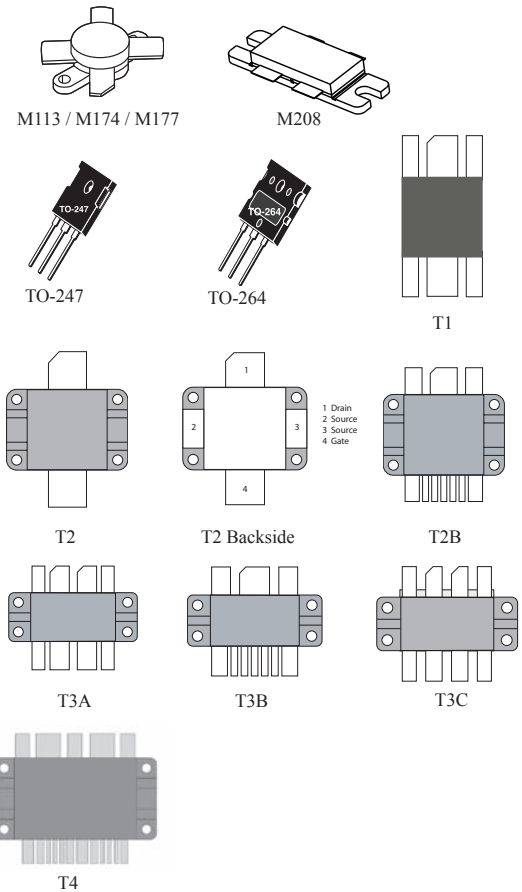
*Current ratings per leg

High Voltage RF MOSFETs

The ARF family of RF Power MOSFETs are optimized for applications requiring frequencies as high as 150MHz and operating voltages as high as 400V. Historically, RF Power MOSFETs were limited to applications of 50V or less. This limitation has been removed by combining Microsemi's high voltage MOSFET technology with RF specific die geometries.

Why Higher Voltage? Higher V_{DD} means higher load impedance. For 150W output from a 50V supply the load impedance is only 8 ohms. At 125V, the load impedance is 50 ohms. The higher impedance allows simpler transformers and combiners. Paralleled devices can still operate into reasonable and convenient impedances. The increased operating voltage also lowers the DC current required for any given power output increasing efficiency and reducing the size, weight and cost of other system components.

Pout (W)	Freq. (MHz)	V_{DD}/BV_{DSS} (V)	θ_{JC} ($^{\circ}C/W$)	Package Style	Part Number	Class of Operation
90	120	150V/450V	0.76	TO-247	ARF449AG/BG	C-E
100	100	125V/500V	0.70	TO-247	ARF463AG/BG	A-E
		125V/500V	0.70	TO-247	ARF463AP1G/BP1G	A-E
140	65	250V/900V	0.55	TO-247	ARF446G	C-E
		250V/900V	0.55	TO-247	ARF447G	C-E
		150V/450V	0.55	TO-247	ARF448AG/BG	C-E
150	65	125V/500V	0.50	TO-247	ARF460AG/BG	A-E
		250V/1kV	0.50	TO-247	ARF461AG/BG	A-E
		300V/1.2kV	0.50	TO-247	ARF465AG/BG	A-E
150	100	165V/500V	0.70	M174	ARF520	A-E
		165V/500V	0.60	M174	ARF521	A-E
300	150	165V/500V	0.35	M208	ARF473	A-E
		165V/500V	0.31	T3A	ARF475FL	A-E
		165V/500V	0.31	T3C	ARF476FL	A-E
300	45	200V/1kV	0.35	TO-264	ARF466AG/BG	A-E
		200V/1kV	0.27	T2	ARF466FL	A-E
		200V/1kV	0.27	T2	ARF467FL	A-E
750	25	250V/1000V	0.13	T2	ARF1519	A-E
750	40	125V/500V	0.12	T1	ARF1500	A-E
		250V/1kV	0.12	T1	ARF1501	A-E
		300V/1.2kV	0.12	T1	ARF1505	A-E
750	40	400V/1000V	0.12	T1	ARF1510	D
		380V/500V	0.12	T1	ARF1511	D



Drivers and Driver-RF MOSFET Hybrids

RF MOSFET performance can be severely limited by the driver selection. The DRF100 and DRF200G Drivers have been optimized to drive RF power MOSFETs. The DRF100 is able to drive RF MOSFETs with greater than 3nF gate capacitance to 15 volts at 30MHz. The DRF1200/01/02/03 Hybrids integrates Driver, bypass capacitors and RF MOSFETs into a single package. Integration maximizes amplifier performance by minimizing transmission line parasitics between the Driver and MOSFET. The DRF1300 or DRF1301 has two independent channels, each containing a Driver and RF MOSFET in a push pull configuration. The DRF1400A and B are half bridge hybrids with symmetrically orientated leads so that the two can easily be configured into a full bridge converter. All DRF parts feature a proprietary Anti-ring function to eliminate cross conduction in a Bridge or push-pull topologies. All DRF parts except the DRF200G (non-inverting only) can be externally selected in either an inverting or non-inverting configuration.

Pout (W)	Freq. (MHz)	V_{DD}/BV_{DSS} (V)	θ_{JC} ($^{\circ}C/W$)	Package Style	Part Number	Class of Operation	Description
50	50	15V/-	1.40	T3B	DRF100	D-E	High Speed MOSFET Driver
50	30	15V/-	1.40	TO-247	DRF200G	D-E	MOSFET Driver
560	30	15V/1000V	1.00	T2B	DRF1200	D-E	Driver and High Voltage RF MOSFET
2000	30	15V/1000V	.025	T2B	DRF1201	D-E	Driver and High Voltage/High Power RF MOSFET
2000	30	15V/500V	.025	T2B	DRF1202	D-E	Driver and High Power RF MOSFET
650	30	15V/1000V	0.09	T2B	DRF1203	D-E	Driver and High Voltage RF MOSFET
1500	30	15V/500V	0.06	T4	DRF1300	D-E	2 Drivers/RF MOSFETs in Push-Pull Configuration
1500	30	15V/1000	0.06	T4	DRF1301	D-E	2 Drivers/RF MOSFETs in Push-Pull Configuration
2500	30	15V/500	0.06	T4	DRF1400A/B	D-E	2 Drivers/RF MOSFETs in a H Bridge Configuration

High Frequency RF MOSFETs

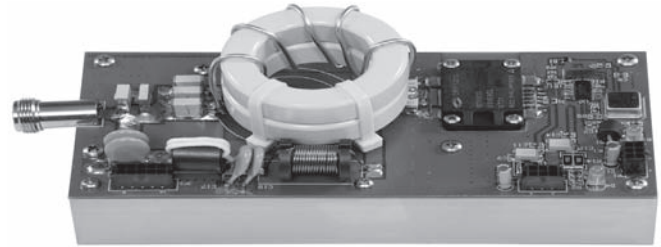
The VRF family of RF MOSFETs are improved replacements for industry standard RF transistors. They provide improved ruggedness by increasing the BV_{DSS} over 30% from the industry standard of 125 volts to 170V minimum. Low cost flangeless packages - Microsemi is dedicated to optimizing the performance, reducing cost and improving reliability. We will continue to offer a greater number of product offerings in the new reduced cost Flangeless packages.

Pout Min (W)	Pin Max (W)	Gain Typ (dB)	η Typ (%)	V_{DD}/BV_{DSS} (V)	Coss Type (pF)	VSWR Load	θ_{JC} (°C/W)	Case Style	Part Number
150	15.00	10	45	28V/65V	420	30:1	0.6	M174	VRF141
30	1.00	15	50	50V/165V	35	30:1	1.5	M113	VRF148A
150	15.00	10	50	50V/165V	230	30:1	0.6	M174	VRF150
150	6.00	14	50	50V/165V	235	30:1	0.6	M174	VRF151
300	6.00	14	55	50V/165V	220	5:1	0.35	M208	VRF151G
600	16.00	17	45	50V/165V	1000	-	0.13	T2	VRF154FL
600	16.00	21	45	50V/165V	750	-	0.13	T2	VRF157FL
300	2.70	20	65	50V/165V	370	3:1	0.27	M177	VRF2933

Reference Design Kits

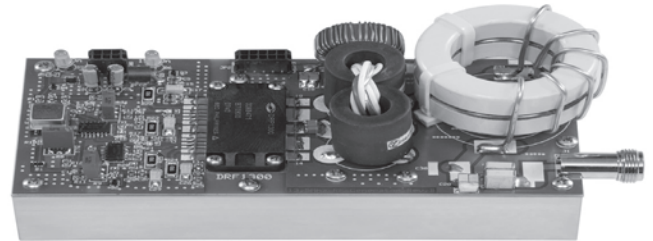
DRF1200/CLASS-E

The DRF1200/CLASS-E Single Ended RF Generator is a reference design providing the designer the ability to evaluate an 85% efficient 1000W CLASS-E RF Generator



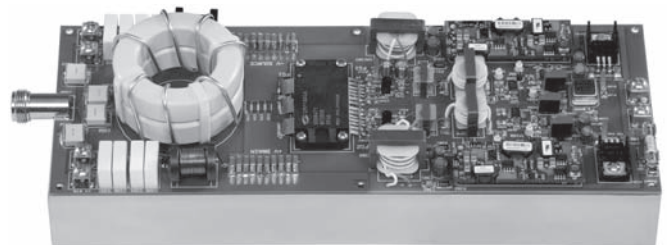
DRF1300/CLASS-D

The DRF1300/CLASS-D Push Pull RF Generator is a reference design providing the designer the ability to evaluate an 80% efficient 2000W CLASS-D RF Generator



DRF1400/CLASS-D

The DRF1400/CLASS-D Half Bridge RF Generator is a reference design providing the designer the ability to evaluate an 86% efficient 3000W CLASS-D RF Generator



All kits include: A fully populated board attached to an aluminum heat sink. An extensive application note explaining the theory of operation with designers recommendations for evaluation and board layout. All key waveforms are illustrated and described. A complete parts list with recommended vendor part numbers and the board's Gerber file are provided for an easy transition into an end application.

POWER MODULES

Microsemi combines a formidable array of technologies in semiconductors, packaging, and automated manufacturing to produce a wide range of high quality modules optimized for:

- Reliability
- Efficiency and electrical performance
- Low cost
- Space savings
- Reduced assembly time



The readily available standard module product line spans a wide selection of circuit topologies, semiconductors including silicon carbide, voltage and current ratings, and packages. If you need even more flexibility or intellectual property protection, Microsemi can often customize a standard power module with no setup cost and with a short lead time. Unique requirements can be met with Application Specific Power Modules (ASPM®).

In addition to industrial, UPS, SMPS, and motor drive applications, Microsemi serves Hi-Rel applications. A wide selection of construction materials enables Microsemi to manufacture with short lead times modules that feature:

- Extended temperature range: -60°C to +200°C
- Reduced size and weight
- Extended reliability
- Hi-Rel testing and screening options

Microsemi's experience and expertise in power electronic conversion brings the most effective technical support for your new development. Here is how we can help with your application:

- Isolated gate driver & supply
- Short circuit protection
- Snubbers
- Temperature & current sensing
- Mix & match semiconductors
- Parameter binning

Power Module Part Numbering System

IGBT Modules	APT	G = IGBT module	Speed	Current @ Tc=80°C	Circuit	Voltage	Suffix
				S Low Loss IGBT F Fast IGBT U Ultra Fast IGBT T Trench Gate IGBT	X 1	A Phase Leg H Full Bridge U Single Switch X 3 Phase Inverter DH Asymmetric Bridge DA Boost Chopper SK Buck Chopper DDA Double Boost Chopper DSK Double Buck Chopper DU Dual Common Source TA Triple Phase Leg TDU Triple Dual Common Source	/ 10

APT G F 300 U 120 DAG

MOSFET Modules	APT	M = MOSFET module C = CoolMOST™ module	Voltage	Circuit	Rdson	Suffix
				/ 10	A Phase Leg H Full Bridge U Single Switch X 3 Phase Inverter DH Asymmetric Bridge DA Boost Chopper SK Buck Chopper DDA Double Boost Chopper DSK Double Buck Chopper DU Dual Common Source TA Triple Phase Leg TDU Triple Dual Common Source	if>100 : / 10 if<100 : M value

APT C 60 A M18 SCTG

CoolMOST™ is a trademark of Infineon Technologies

Diode Modules	APT	D= Diode module	Type	Current	Circuit	Voltage	Suffix
				C SiC F FRED SK Schottky R Standard Rectifier	X 1	U Single H Bridge DH Dual Bridge AA Dual Common Anode KK Dual Common Cathode AK Dual Diodes X Three Phase Bridge Rectifier	/ 10

APT D F 400 AK 60 G

POWER MODULE PACKAGES

Microsemi's power module packages cover a complete line of industry standard packages as well as new low profile packages featuring lower cost, less stray inductance, and lower parasitic resistance for higher efficiency, higher frequency capability, and lower EMI.

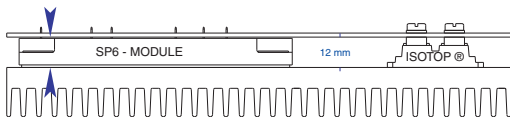
- Lower cost
- Reduced stray inductance
- Reduced parasitic resistance
- Higher efficiency
- Higher frequency capability
- Lower EMI

Improved Low Profile Packages

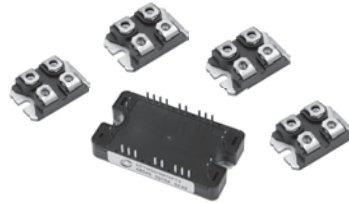
- SP1 (12mm)
- SP3 (12mm)
- SP4 (17mm)
- SP6 (17mm)
- SP6-P (12mm)



Package Advantages



SP1 package:
 -Replaces 2 SOT-227 parts
 -Improved assembly time and cost
 -Height compatible with SOT-227 package
 -Copper base plate for improved performance



SP6 package offers the same footprint and the same pinout location as the popular 62mm package but with lower height, leading to:
 - Reduced stray inductance
 - Reduced parasitic resistance
 - Higher efficiency at high frequency

SP3 package:
 -Replaces up to 4 SOT-227 parts
 -Reduced assembly time and cost
 -Height compatible with SOT-227 package
 -Copper base plate for high reliability



SP6-P package:
 -Replaces up to 6 SOT-227 parts
 -Height compatible with SOT-227 package
 -Low inductance solder pins
 -High current capability

Industry Standard Packages

SOT-227 (Isotop®)



SOT-227

Econo Types

- E2 (Long Pins)
- P2 (Short Pins)
- E3 & P3 (Short Pins Only)



E2



P2



E3/P3

34mm & 62mm Types

- D1 (34 mm Wide)
- D3 (62 mm Wide)
- D4 (62 mm Wide)



D1



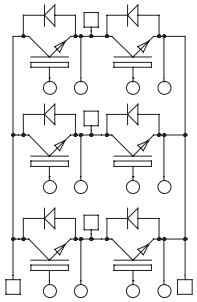
D3



D4

IGBT Power Modules

3 PHASE BRIDGE (SP3 package)



V_{CES} (V)	IGBT Type	I_C (A) $T_c=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_C	Package Style	NTC	Part Number
600	NPT	30	2.1	SP3	YES	APTGF30X60T3G
		50	2.1	SP3	YES	APTGF50X60T3G
	TRENCH	20	1.5	SP3	YES	APTGT20X60T3G
		30	1.5	SP3	YES	APTGT30X60T3G
		50	1.5	SP3	YES	APTGT50X60T3G
		75	1.5	SP3	YES	APTGT75X60T3G
1200	NPT	15	3.2	SP3	YES	APTGF15X120T3G
		25	3.2	SP3	YES	APTGF25X120T3G
	TRENCH	25	1.7	SP3	YES	APTGT25X120T3G
		35	1.7	SP3	YES	APTGT35X120T3G

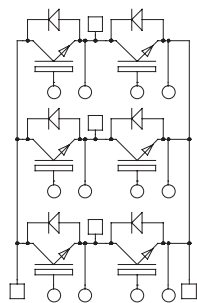


SP3



E2

3 PHASE BRIDGE (long pin package)

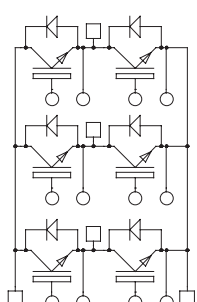


V_{CES} (V)	IGBT Type	I_C (A) $T_c=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_C	Package Style	NTC	Part Number
600	NPT	20	2.1	E2	-	APTGF20X60E2G
		30	2.1	E2	-	APTGF30X60E2G
		50	2.1	E2	-	APTGF50X60E2G
1200	NPT	10	3.2	E2	-	APTGF10X120E2G
		15	3.2	E2	-	APTGF15X120E2G
		25	3.2	E2	-	APTGF25X120E2G
		50	3.2	E2	-	APTGF50X120E2G
1700	NPT	50	3.2	E2	-	APTGS50X170E2G



P2

3 PHASE BRIDGE (short pin package)

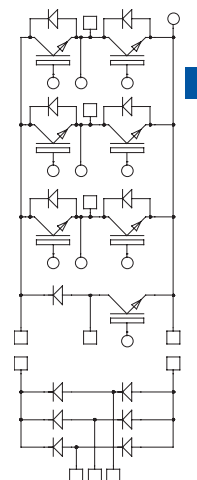


V_{CES} (V)	IGBT Type	I_C (A) $T_c=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_C	Package Style	NTC	Part Number
600	NPT	50	2.1	P2	-	APTGF50X60P2G
		90	2.1	E3	YES	APTGF90X60TE3G
		150	2.1	E3	-	APTGF150X60E3G
		150	2.1	E3	YES	APTGF150X60TE3G
1200	NPT	25	3.2	P2	-	APTGF25X120P2G
		50	3.2	P2	-	APTGF50X120P2G
		50	3.2	E3	YES	APTGF50X120TE3G
	Field Stop Trench	75	1.7	E3	-	APTGT75X120E3G
		75	1.7	E3	YES	APTGT75X120TE3G
		100	1.7	E3	-	APTGT100X120E3G
		100	1.7	E3	YES	APTGT100X120TE3G
		150	1.7	E3	-	APTGT150X120E3G
1700	NPT	75	3.5	E3	YES	APTGS75X170TE3G



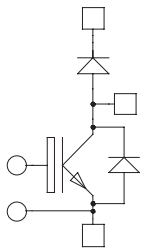
E3/P3

3 PHASE BRIDGE + RECTIFIER



V_{CES} (V)	IGBT Type	I_C (A) $T_c=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_C	Package Style	NTC	Part Number
600	NPT	50	2.1	P3	YES	APTGF50X60RTP3G
		50	2.1	P3	YES	APTGF50X60BTP3G
1200	NPT	25	2.5	P2	YES	APTGS25X120RTP2G
		25	2.5	P2	YES	APTGS25X120BTP2G
	Field Stop Trench	35	1.7	P3	YES	APTGT35X120RTP3G
		35	1.7	P3	YES	APTGT35X120BTP3G
		50	1.7	P3	YES	APTGT50X120RTP3G
		75	1.7	P3	YES	APTGT75X120BTP3G
1700	Trench	50	2.0	P3	YES	APTGT50X170BTP3G

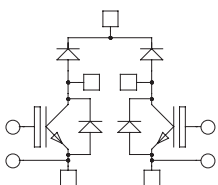
BOOST CHOPPER



V_{CES} (V)	IGBT Type	I_C (A) $T_C=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_C	Package Style	NTC	Part Number
600	NPT	30	2.1	ISOTOP®	-	APT30GF60JU2
		50	2.1	ISOTOP®	-	APT50GF60JU2
		60	2.1	ISOTOP®	-	APT60GF60JU2
		75	2.1	D1	-	APTGF75DA60D1G
		90	2.1	SP1	YES	APTGF90DA60T1G
		90	2.1	SP4	YES	APTGF90DA60TG
		100	2.1	ISOTOP®	-	APT100GF60JU2
		165	2.0	D1	-	APTGF165DA60D1G
		180	2.1	SP4	YES	APTGF180DA60TG
	Field Stop Trench	330	2.0	D3	-	APTGF330DA60D3G
		350	2.1	SP6	-	APTGF350DA60G
		75	1.5	SP1	YES	APTGT75DA60T1G
		100	1.5	SP1	YES	APTGT100DA60T1G
		100	1.5	SP4	YES	APTGT100DA60TG
		150	1.5	SP1	YES	APTGT150DA60T1G
		150	1.5	SP4	YES	APTGT150DA60TG
		200	1.5	SP4	YES	APTGT200DA60TG
		300	1.4	SP6	-	APTGT300DA60G
1200	NPT	50	3.2	SP1	YES	APTGF50DA120T1G
		50	3.2	SP4	YES	APTGF50DA120TG
		75	3.2	SP1	YES	APTGF75DA120T1G
		100	3.2	SP1	YES	APTGF100DA120T1G
		100	3.2	SP4	YES	APTGF100DA120TG
		150	3.2	SP4	YES	APTGF150DA120TG
	Field Stop Trench	300	3.2	SP6	-	APTGF300DA120G
		35	1.7	ISOTOP®	-	APT35GT120JU2
		50	1.7	ISOTOP®	-	APT50GT120JU2
		50	1.7	D1	-	APTGT50DA120D1G
		50	1.7	SP4	YES	APTGT50DA120TG
		75	1.7	ISOTOP®	-	APT75GT120JU2
		75	1.7	SP1	YES	APTGT75DA120T1G
		75	1.7	SP4	YES	APTGT75DA120TG
		100	1.7	SP1	YES	APTGT100DA120T1G
		100	1.7	ISOTOP®	-	APT100GT120JU2
		100	1.7	D1	-	APTGT100DA120D1G
		100	1.7	SP4	YES	APTGT100DA120TG
1700	Field Stop Trench	150	1.7	SP6	-	APTGT150DA120G
		150	1.7	D1	-	APTGT150DA120D1G
		150	1.7	SP4	YES	APTGT150DA120TG
		200	1.7	SP6	-	APTGT200DA120G
		200	1.7	D3	-	APTGT200DA120D3G
		300	1.7	SP6	-	APTGT300DA120G
		300	1.7	D3	-	APTGT300DA120D3G
		400	1.7	SP6	-	APTGT400DA120G
		30	2.0	SP1	YES	APTGT30DA170T1G
		50	2.0	SP1	YES	APTGT50DA170T1G
		50	2.0	SP4	YES	APTGT50DA170TG
		75	2.0	SP1	YES	APTGT75DA170T1G
75	2.0	D1	-	APTGT75DA170D1G		
100	2.0	D1	-	APTGT100DA170D1G		
100	2.0	SP4	YES	APTGT100DA170TG		
150	2.0	SP6	-	APTGT150DA170G		
150	2.0	D3	-	APTGT150DA170D3G		
225	2.0	SP6	-	APTGT225DA170G		
300	2.0	SP6	-	APTGT300DA170G		



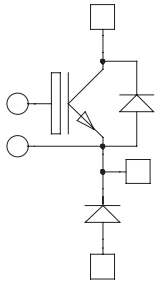
DUAL BOOST CHOPPER



V_{CES} (V)	IGBT Type	I_C (A) $T_C=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_C	Package Style	NTC	Part Number
600	NPT	50	2.1	SP3	YES	APTGF50DDA60T3G
	Field Stop Trench	20	1.5	SP3	YES	APTGT20DDA60T3G
		30	1.5	SP3	YES	APTGT30DDA60T3G
		50	1.5	SP3	YES	APTGT50DDA60T3G
		75	1.5	SP3	YES	APTGT75DDA60T3G
		100	1.5	SP3	YES	APTGT100DDA60T3G
1200	NPT	25	3.2	SP3	YES	APTGF25DDA120T3G
		75	3.2	SP4	YES	APTGF75DDA120TG
		50	1.7	SP3	YES	APTGT50DDA120T3G

IGBT Power Modules

BUCK CHOPPER



V _{CES} (V)	IGBT Type	I _C (A) T _c =80° C	V _{CE(ON)} at rated I _c	Package Style	NTC	Part Number
600	NPT	30	2.1	ISOTOP®	-	APT30GF60JU3
		50	2.1	ISOTOP®	-	APT50GF60JU3
		60	2.1	ISOTOP®	-	APT60GF60JU3
		90	2.1	SP1	YES	APTGF90SK60T1G
		90	2.1	SP4	YES	APTGF90SK60TG
		100	2.1	ISOTOP®	-	APT100GF60JU3
		165	2.0	D1	-	APTGF165SK60D1G
		180	2.1	SP4	YES	APTGF180SK60TG
	350	2.1	SP6	-	APTGF350SK60G	
	Field Stop Trench	75	1.5	SP1	YES	APTGT75SK60T1G
		100	1.5	SP1	YES	APTGT100SK60T1G
		100	1.5	SP4	YES	APTGT100SK60TG
		150	1.5	SP1	YES	APTGT150SK60T1G
		150	1.5	SP4	YES	APTGT150SK60TG
		200	1.5	SP4	YES	APTGT200SK60TG
		300	1.4	SP6	-	APTGT300SK60G
450		1.4	SP6	-	APTGT450SK60G	
600	1.4	SP6	-	APTGT600SK60G		
1200	NPT	50	3.2	SP1	YES	APTGF50SK120T1G
		50	3.2	SP4	YES	APTGF50SK120TG
		100	3.2	SP4	YES	APTGF100SK120TG
		150	3.2	SP4	YES	APTGF150SK120TG
		300	3.2	SP6	-	APTGF300SK120G
	Field Stop Trench	35	1.7	ISOTOP®	-	APT35GT120JU3
		50	1.7	ISOTOP®	-	APT50GT120JU3
		50	1.7	SP4	YES	APTGT50SK120TG
		75	1.7	SP1	YES	APTGT75SK120T1G
		75	1.7	SP4	YES	APTGT75SK120TG
		75	1.7	ISOTOP®	-	APT75GT120JU3
		100	1.7	ISOTOP®	-	APT100GT120JU3
		100	1.7	SP4	YES	APTGT100SK120TG
		150	1.7	SP6	-	APTGT150SK120G
		150	1.7	SP4	YES	APTGT150SK120TG
		200	1.7	SP6	-	APTGT200SK120G
		200	1.7	D3	-	APTGT200SK120D3G
		300	1.7	SP6	-	APTGT300SK120G
		400	1.7	SP6	-	APTGT400SK120G
		1700	Field Stop Trench	30	2.0	SP1
50	2.0			SP1	YES	APTGT50SK170T1G
50	2.0			SP4	YES	APTGT50SK170TG
100	2.0			SP4	YES	APTGT100SK170TG
150	2.0			SP6	-	APTGT150SK170G
225	2.0			SP6	-	APTGT225SK170G
300	2.0			SP6	-	APTGT300SK170G
300	2.0			D3	-	APTGT300SK170D3G



SOT-227



SP1



SP3

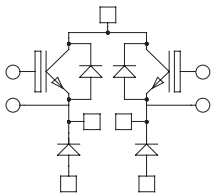


SP4



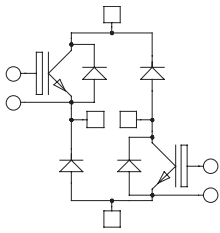
SP6

DUAL BUCK CHOPPER



V _{CES} (V)	IGBT Type	I _C (A) T _c =80° C	V _{CE(ON)} at rated I _c	Package Style	NTC	Part Number
600	NPT	50	2.1	SP3	YES	APTGF50DSK60T3G
	Field Stop Trench	20	1.5	SP3	YES	APTGT20DSK60T3G
		30	1.5	SP3	YES	APTGT30DSK60T3G
		50	1.5	SP3	YES	APTGT50DSK60T3G
		75	1.5	SP3	YES	APTGT75DSK60T3G
		100	1.5	SP3	YES	APTGT100DSK60T3G
1200	NPT	25	3.2	SP3	YES	APTGF25DSK120T3G
	Field Stop	75	3.2	SP4	YES	APTGF75DSK120TG
		50	1.7	SP3	YES	APTGT50DSK120T3G

ASYMMETRICAL BRIDGE



V_{CES} (V)	IGBT Type	I_C (A) $T_C=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_C	Package Style	NTC	Part Number
600	NPT	50	2.1	SP4	YES	APTF50DH60TG
		90	2.1	SP4	YES	APTF90DH60TG
		180	2.1	SP6	-	APTF180DH60G
	Field Stop Trench	50	1.5	SP4	YES	APTGT50DH60TG
		75	1.5	SP4	YES	APTGT75DH60TG
		100	1.5	SP4	YES	APTGT100DH60TG
		150	1.5	SP4	YES	APTGT150DH60TG
		200	1.5	SP6	-	APTGT200DH60G
1200	NPT	50	3.2	SP4	YES	APTF50DH120TG
		75	3.2	SP4	YES	APTF75DH120TG
		150	3.2	SP6	-	APTF150DH120G
	Field Stop Trench	50	1.7	SP4	YES	APTGT50DH120TG
		75	1.7	SP4	YES	APTGT75DH120TG
		100	1.7	SP4	YES	APTGT100DH120TG
		150	1.7	SP6	-	APTGT150DH120G
		200	1.7	SP6	-	APTGT200DH120G
1700	Field Stop Trench	50	2.0	SP4	YES	APTGT50DH170TG
		100	2.0	SP6	-	APTGT100DH170G
		150	2.0	SP6	-	APTGT150DH170G

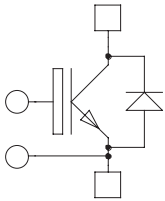


D4



SP4

SINGLE SWITCH

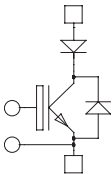


V_{CES} (V)	IGBT Type	I_C (A) $T_C=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_C	Package Style	NTC	Part Number
600	NPT	200	2.1	D4	-	APTF200U60D4G
		300	2.1	D4	-	APTF300U60D4G
		360	2.0	D4	-	APTF360U60D4G
		500	2.0	D4	-	APTF500U60D4G
		660	2.0	D4	-	APTF660U60D4G
1200	Field Stop Trench	200	1.7	D4	-	APTGT200U120D4G
		300	1.7	D4	-	APTGT300U120D4G
		400	1.7	D4	-	APTGT400U120D4G
		600	1.7	D4	-	APTGT600U120D4G
1700	Field Stop Trench	200	2.0	D4	-	APTGT200U170D4G
		300	2.0	D4	-	APTGT300U170D4G
		400	2.0	D4	-	APTGT400U170D4G
		600	2.0	D4	-	APTGT600U170D4G



SP6

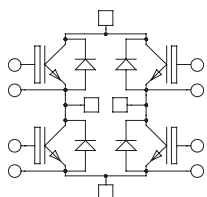
SINGLE SWITCH + SERIES DIODE



V_{CES} (V)	IGBT Type	I_C (A) $T_C=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_C	Package Style	NTC	Part Number
1200	NPT	200	3.2	SP6	-	APTF200U120DG
		300	3.2	SP6	-	APTF300U120DG

IGBT Power Modules

FULL BRIDGE



V_{CES} (V)	IGBT Type	I_c (A) $T_c=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_c	Package Style	NTC	Part Number		
600	NPT	30	2.1	SP1	YES	APTGF30H60T1G		
		30	2.1	SP3	YES	APTGF30H60T3G		
		50	2.1	SP1	YES	APTGF50H60T1G		
		50	2.1	SP3	YES	APTGF50H60T3G		
		90	2.1	SP4	YES	APTGF90H60TG		
		180	2.1	SP6	-	APTGF180H60G		
	Field Stop Trench	20	1.5	SP1	YES	APTGT20H60T1G		
		20	1.5	SP3	YES	APTGT20H60T3G		
		30	1.5	SP1	YES	APTGT30H60T1G		
		30	1.5	SP3	YES	APTGT30H60T3G		
		50	1.5	SP1	YES	APTGT50H60T1G		
		50	1.5	SP3	YES	APTGT50H60T3G		
		75	1.5	SP1	YES	APTGT75H60T1G		
		75	1.5	SP3	YES	APTGT75H60T3G		
		100	1.5	SP4	YES	APTGT100H60TG		
		100	1.5	SP3	YES	APTGT100H60T3G		
		150	1.5	SP4	YES	APTGT150H60TG		
		200	1.5	SP6	-	APTGT200H60G		
300	1.4	SP6	-	APTGT300H60G				
1200	NPT	15	3.2	SP1	YES	APTGF15H120T1G		
		15	3.2	SP3	YES	APTGF15H120T3G		
		25	3.2	SP1	YES	APTGF25H120T1G		
		25	3.2	SP3	YES	APTGF25H120T3G		
		50	3.2	SP4	YES	APTGF50H120TG		
		75	3.2	SP4	YES	APTGF75H120TG		
	Field Stop Trench	150	3.2	SP6	-	APTGF150H120G		
		25	1.7	SP1	YES	APTGT25H120T1G		
		35	1.7	SP1	YES	APTGT35H120T1G		
		35	1.7	SP3	YES	APTGT35H120T3G		
		50	1.7	SP4	YES	APTGT50H120TG		
		50	1.7	SP3	YES	APTGT50H120T3G		
		75	1.7	SP4	YES	APTGT75H120TG		
		100	1.7	SP6	-	APTGT100H120G		
		150	1.7	SP6	-	APTGT150H120G		
		200	1.7	SP6	-	APTGT200H120G		
		1700	Field Stop Trench	30	2.0	SP3	YES	APTGT30H170T3G
				50	2.0	SP4	YES	APTGT50H170TG
100	2.0			SP6	-	APTGT100H170G		
150	2.0			SP6	-	APTGT150H170G		



SP1



SP3

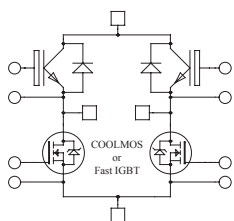


SP4



SP6

FULL BRIDGE

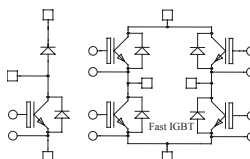


V_{CES} (V)	Technology	I_c (A) $T_c=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_c	Package Style	NTC	Part Number
600	DC/AC Inverter (NPT/Trench IGBT)	30	2.1/1.5	SP3	YES	APTVG30H60T3G
		50	2.1/1.5	SP3	YES	APTVG50H60T3G
		75	2.1/1.5	SP3	YES	APTVG75H60T3G
		100	2.1/1.5	SP3	YES	APTVG100H60T3G
	DC/AC Inverter (COOLMOS/TRENCH)	50	83mR/1.5	SP1	YES	APTCV40H60CT1G
1200	DC/AC Inverter (NPT/Trench IGBT)	50	45mR/1.5	SP3	YES	APTCV50H60T3G
		15	3.2/1.7	SP3	YES	APTVG15H120T3G
		25	3.2/1.7	SP3	YES	APTVG25H120T3G
		50	3.2/1.7	SP3	YES	APTVG50H120T3G



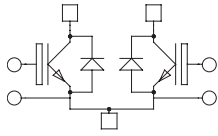
SP6-P

BOOST CHOPPER + FULL BRIDGE



V_{CES} (V)	Technology	I_c (A) $T_c=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_c	Package Style	NTC	Part Number
600	DC/AC Inverter (NPT/Trench IGBT)	50	2.1/1.5	SP4	-	APTVG50H60BG
		100	2.1/1.5	SP6-P	YES	APTVG100H60BTPG
1200	DC/AC Inverter (NPT/Trench IGBT)	25	3.2/1.7	SP4	-	APTVG25H120BG
		50	3.2/1.7	SP6-P	YES	APTVG50H120BTPG

DUAL COMMON SOURCE



V _{CES} (V)	IGBT Type	I _c (A) T _c =80° C	V _{CE(ON)} at rated I _c	Package Style	NTC	Part Number	
600	NPT	90	2.1	SP4	YES	APTGF90DU60TG	
		180	2.1	SP4	YES	APTGF180DU60TG	
		350	2.1	SP6	-	APTGF350DU60G	
	Field Stop Trench	Field Stop Trench	100	1.5	SP4	YES	APTGT100DU60TG
			150	1.5	SP4	YES	APTGT150DU60TG
			200	1.5	SP4	YES	APTGT200DU60TG
			300	1.4	SP6	-	APTGT300DU60G
450			1.4	SP6	-	APTGT450DU60G	
600			1.4	SP6	-	APTGT600DU60G	
1200	NPT	50	3.2	SP4	YES	APTGF50DU120TG	
		100	3.2	SP4	YES	APTGF100DU120TG	
		150	3.2	SP4	YES	APTGF150DU120TG	
		300	3.2	SP6	-	APTGF300DU120G	
	Field Stop Trench	Field Stop Trench	50	1.7	SP4	YES	APTGT50DU120TG
			75	1.7	SP4	YES	APTGT75DU120TG
			100	1.7	SP4	YES	APTGT100DU120TG
			150	1.7	SP6	-	APTGT150DU120G
			150	1.7	SP4	YES	APTGT150DU120TG
			200	1.7	SP6	-	APTGT200DU120G
			300	1.7	SP6	-	APTGT300DU120G
1700	Field Stop Trench	50	2.0	SP4	YES	APTGT50DU170TG	
		100	2.0	SP4	YES	APTGT100DU170TG	
		150	2.0	SP6	-	APTGT150DU170G	
		225	2.0	SP6	-	APTGT225DU170G	
300	2.0	SP6	-	APTGT300DU170G			



SP4

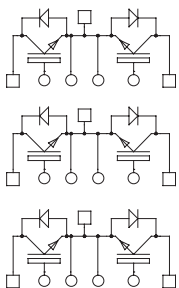


SP6



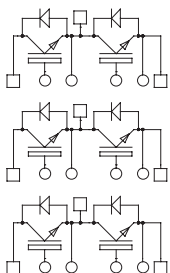
SP6-P

TRIPLE DUAL COMMON SOURCE



V _{CES} (V)	IGBT Type	I _c (A) T _c =80° C	V _{CE(ON)} at rated I _c	Package Style	NTC	Part Number
600	NPT	90	2.1	SP6-P	-	APTGF90TDU60PG
		50	1.5	SP6-P	-	APTGT50TDU60PG
	Field Stop Trench	75	1.5	SP6-P	-	APTGT75TDU60PG
		100	1.5	SP6-P	-	APTGT100TDU60PG
		150	1.5	SP6-P	-	APTGT150TDU60PG
1200	NPT	50	3.2	SP6-P	-	APTGF50TDU120PG
	Field Stop	75	1.7	SP6-P	-	APTGT75TDU120PG
1700	Field Stop	50	2.0	SP6-P	-	APTGT50TDU170PG

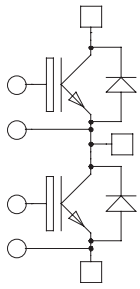
TRIPLE PHASE LEG



V _{CES} (V)	IGBT Type	I _c (A) T _c =80° C	V _{CE(ON)} at rated I _c	Package Style	NTC	Part Number
600	NPT	90	2.1	SP6-P	-	APTGF90TA60PG
		50	1.5	SP6-P	-	APTGT50TA60PG
	Field Stop Trench	75	1.5	SP6-P	-	APTGT75TA60PG
		100	1.5	SP6-P	-	APTGT100TA60PG
		150	1.5	SP6-P	-	APTGT150TA60PG
1200	NPT	50	3.2	SP6-P	-	APTGF50TA120PG
	Field Stop	75	1.7	SP6-P	-	APTGT75TA120PG
1700	Field Stop	50	2.0	SP6-P	-	APTGT50TA170PG

IGBT Power Modules

PHASE LEG



V_{CES} (V)	IGBT Type	I_c (A) $T_c=80^\circ\text{C}$	$V_{CE(ON)}$ at rated I_c	Package Style	NTC	Part Number	
600	NPT	30	2.1	SP1	YES	APTGF30A60T1G	
		50	2.1	SP1	YES	APTGF50A60T1G	
		90	2.1	SP1	YES	APTGF90A60T1G	
		90	2.0	D1	-	APTGF90A60D1G	
		90	2.1	SP4	YES	APTGF90A60TG	
		165	2.0	D1	-	APTGF165A60D1G	
		180	2.0	D3	-	APTGF180A60D3G	
		180	2.1	SP4	YES	APTGF180A60TG	
		330	2.0	D3	-	APTGF330A60D3G	
		350	2.1	SP6	-	APTGF350A60G	
	Field Stop Trench	20	1.5	SP1	YES	APTGT20A60T1G	
		30	1.5	SP1	YES	APTGT30A60T1G	
		50	1.5	SP1	YES	APTGT50A60T1G	
		75	1.5	SP1	YES	APTGT75A60T1G	
		100	1.5	SP1	YES	APTGT100A60T1G	
		100	1.5	SP4	YES	APTGT100A60TG	
		150	1.5	SP1	YES	APTGT150A60T1G	
		150	1.5	SP4	YES	APTGT150A60TG	
		200	1.5	SP4	YES	APTGT200A60TG	
		300	1.4	SP6	-	APTGT300A60G	
450	1.4	SP6	-	APTGT450A60G			
600	1.4	SP6	-	APTGT600A60G			
1200	NPT	15	3.2	SP1	YES	APTGF15A120T1G	
		25	3.2	SP1	YES	APTGF25A120T1G	
		50	3.2	SP1	YES	APTGF50A120T1G	
		50	3.2	SP4	YES	APTGF50A120TG	
		100	3.2	SP4	YES	APTGF100A120TG	
		150	3.2	SP4	YES	APTGF150A120TG	
		300	3.2	SP6	-	APTGF300A120G	
		Field Stop Trench	25	1.7	SP1	YES	APTGT25A120T1G
			25	1.7	D1	-	APTGT25A120D1G
			35	1.7	SP1	YES	APTGT35A120T1G
	50		1.7	SP1	YES	APTGT50A120T1G	
	50		1.7	D1	-	APTGT50A120D1G	
	50		1.7	SP4	YES	APTGT50A120TG	
	75		1.7	SP1	YES	APTGT75A120T1G	
	75		1.7	SP4	YES	APTGT75A120TG	
	100		1.7	D1	-	APTGT100A120D1G	
	100		1.7	SP4	YES	APTGT100A120TG	
	150	1.7	SP6	-	APTGT150A120G		
	150	1.7	D1	-	APTGT150A120D1G		
	150	1.7	D3	-	APTGT150A120D3G		
150	1.7	SP4	YES	APTGT150A120TG			
200	1.7	SP6	-	APTGT200A120G			
200	1.7	D3	-	APTGT200A120D3G			
300	1.7	SP6	-	APTGT300A120G			
300	1.7	D3	-	APTGT300A120D3G			
400	1.7	SP6	-	APTGT400A120G			
1700	Field Stop Trench	30	2.0	SP1	YES	APTGT30A170T1G	
		50	2.0	SP1	YES	APTGT50A170T1G	
		50	2.0	D1	-	APTGT50A170D1G	
		50	2.0	SP4	YES	APTGT50A170TG	
		75	2.0	D1	-	APTGT75A170D1G	
		100	2.0	SP4	YES	APTGT100A170TG	
		150	2.0	SP6	-	APTGT150A170G	
		150	2.0	D3	-	APTGT150A170D3G	
		200	2.0	D3	-	APTGT200A170D3G	
		225	2.0	SP6	-	APTGT225A170G	
		300	2.0	SP6	-	APTGT300A170G	
		300	2.0	D3	-	APTGT300A170D3G	



D1



D3



SP1

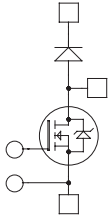


SP4



SP6

BOOST CHOPPER



V _{DSS} (V)	MOSFET Type	R _{DS(ON)} m Ohms	I _D (A) T _C =80° C	Package Style	NTC	Part Number
100	MOS 5	11	100	ISOTOP®	-	APT10M11JV2RU2
	MOS 7	4.5	207	SP4	YES	APTM10DAM05TG
		2.25	370	SP6	-	APTM10DAM02G
200	MOS 5	22	71	ISOTOP®	-	APT20M22JV2RU2
		10	125	SP4	YES	APTM20DAM10TG
	MOS 7	8	147	SP4	YES	APTM20DAM08TG
		5	250	SP6	-	APTM20DAM05G
		4	300	SP6	-	APTM20DAM04G
		MOS 5	100	30	ISOTOP®	-
500	MOS 7	100	30	ISOTOP®	-	APT5010JLLU2
		75	32	ISOTOP®	-	APT50M75JLLU2
		38	64	SP4	YES	APTM50DAM38TG
	MOS 7	35	70	SP4	YES	APTM50DAM35TG
		19	125	SP6	-	APTM50DAM19G
		17	140	SP6	-	APTM50DAM17G
		70	24	SP1	YES	APTC60DAM24T1G
600	COOLMOS	70	40	ISOTOP®	-	APT40N60JCU2
		35	54	SP1	YES	APTC60DAM35T1G
		24	70	ISOTOP®	-	APT50N60JCU2
800	COOLMOS	150	21	SP1	YES	APTC80DA15T1G
		MOS 7	180	33	SP4	YES
1000	MOS 7	90	59	SP6	-	APTM100DAM90G
		180	30	SP1	YES	APTM100DA18T1G
		330	17	SP1	YES	APTM100DA33T1G
	MOS 8	400	15	SP1	YES	APTM120DA40T1G
		290	25	SP4	YES	APTM120DA29TG
1200	MOS 7	150	45	SP6	-	APTM120DA15G
		300	23	SP1	YES	APTM120DA30T1G
		560	13	SP1	YES	APTM120DA56T1G
	MOS 8	680	11	SP1	YES	APTM120DA68T1G



SOT-227



SP1



SP3

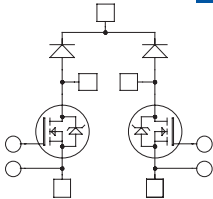


SP4



SP6

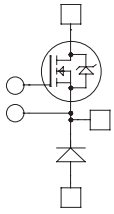
DUAL BOOST CHOPPER



V _{DSS} (V)	MOSFET Type	R _{DS(ON)} m Ohms	I _D (A) T _C =80° C	Package Style	NTC	Part Number
100	MOS 7	19	50	SP3	YES	APTM10DDAM19T3G
		9	100	SP3	YES	APTM10DDAM09T3G
500	MOS 7	100	24	SP3	YES	APTM50DDA10T3G
		65	37	SP3	YES	APTM50DDAM65T3G
600	COOLMOS	70	29	SP3	YES	APTC60DDAM70T3G
		35	54	SP3	YES	APTC60DDAM35T3G
800	COOLMOS	290	11	SP3	YES	APTC80DDA29T3G
		150	21	SP3	YES	APTC80DDA15T3G
1000	MOS 7	350	17	SP3	YES	APTM100DDA35T3G
1200	MOS 7	570	13	SP3	YES	APTM120DDA57T3G

MOSFET Power Modules

BUCK CHOPPER



V _{DSS} (V)	MOSFET Type	R _{DS(ON)} m Ohms	I _D (A) T _c =80° C	Package Style	NTC	Part Number
100	MOS 5	11	100	ISOTOP®	-	APT10M11JVRU3
	MOS 7	4.5	207	SP4	YES	APTM10SKM05TG
		2.25	370	SP6	-	APTM10SKM02G
200	MOS 5	22	71	ISOTOP®	-	APT20M22JVRU3
		10	125	SP4	YES	APTM20SKM10TG
	MOS 7	8	147	SP4	YES	APTM20SKM08TG
		5	250	SP6	-	APTM20SKM05G
		4	300	SP6	-	APTM20SKM04G
500	MOS 5	100	30	ISOTOP®	-	APT50M10JVRU3
		100	30	ISOTOP®	-	APT5010JLLU3
		75	32	ISOTOP®	-	APT50M75JLLU3
	MOS 7	38	64	SP4	YES	APTM50SKM38TG
		35	70	SP4	YES	APTM50SKM35TG
		19	125	SP6	-	APTM50SKM19G
		17	140	SP6	-	APTM50SKM17G
600	COOLMOS	70	40	ISOTOP®	-	APT40N60JCU3
		35	54	SP1	YES	APTC60SKM35T1G
		24	70	SP1	YES	APTC60SKM24T1G
800	COOLMOS	150	21	SP1	YES	APTC80SK15T1G
		180	33	SP4	YES	APTM100SK18TG
1000	MOS 7	90	59	SP6	-	APTM100SKM90G
		400	15	SP1	YES	APTM100SK40T1G
	MOS 8	330	17	SP1	YES	APTM100SK33T1G
		290	25	SP4	YES	APTM120SK29TG
1200	MOS 7	150	45	SP6	-	APTM120SK15G
		680	11	SP1	YES	APTM120SK68T1G
	MOS 8	560	13	SP1	YES	APTM120SK56T1G



SOT-227



SP1

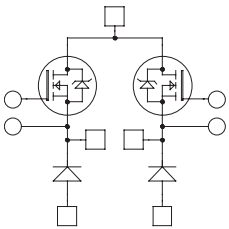


SP3



SP4

DUAL BUCK CHOPPER

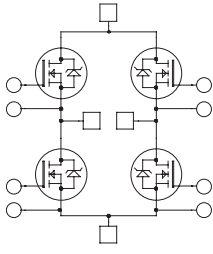


V _{DSS} (V)	MOSFET TYPE	R _{DS(ON)} m Ohms	I _D (A) T _c =80° C	Package Style	NTC	Part Number
100	MOS 7	19	50	SP3	YES	APTM10DSKM19T3G
		9	100	SP3	YES	APTM10DSKM09T3G
500	MOS 7	100	24	SP3	YES	APTM50DSK10T3G
		65	37	SP3	YES	APTM50DSKM65T3G
600	COOLMOS	70	29	SP3	YES	APTC60DSKM70T3G
		35	54	SP3	YES	APTC60DSKM35T3G
800	COOLMOS	290	11	SP3	YES	APTC80DSK29T3G
		150	21	SP3	YES	APTC80DSK15T3G
1000	MOS 7	350	17	SP3	YES	APTM100DSK35T3G
1200	MOS 7	570	13	SP3	YES	APTM120DSK57T3G



SP6

FULL BRIDGE



V _{DSS} (V)	MOSFET TYPE	R _{DS(ON)} m Ohms	I _D (A) T _c =80° C	Package Style	NTC	Part Number
100	FREDFET 7	4.5	207	SP6	-	APTM10HM05FG
		19	50	SP3	YES	APTM10HM19FT3G
		9	100	SP3	YES	APTM10HM09FT3G
		9	100	SP4	YES	APTM10HM09FTG
200	FREDFET 7	20	62	SP4	YES	APTM20HM20FTG
		16	74	SP4	YES	APTM20HM16FTG
		10	125	SP6	-	APTM20HM10FG
		8	147	SP6	-	APTM20HM08FG
500	FREDFET 7	140	18	SP3	YES	APTM50H14FT3G
		100	24	SP3	YES	APTM50H10FT3G
		75	32	SP4	YES	APTM50HM75FTG
		75	32	SP3	YES	APTM50HM75FT3G
		65	37	SP4	YES	APTM50HM65FTG
		65	37	SP3	YES	APTM50HM65FT3G
	38	64	SP6	-	APTM50HM38FG	
	35	70	SP6	-	APTM50HM35FG	
600	FREDFET 8	19	150	SP1	YES	APTM50H15UT1G
		70	29	SP1	YES	APTC60HM70T1G
	COOLMOS	70	29	SP3	YES	APTC60HM70T3G
		45	38	SP1	YES	APTC60HM45T1G
800	FREDFET 8	35	54	SP3	YES	APTC60HM35T3G
		230	15	SP1	YES	APTM60H23UT1G
	COOLMOS	290	11	SP1	YES	APTC80H29T1G
		290	11	SP3	YES	APTC80H29T3G
1000	FREDFET 7	150	29	SP1	YES	APTC80H15T1G
		150	21	SP3	YES	APTC80H15T3G
	FREDFET 8	450	14	SP3	YES	APTM100H45FT3G
		350	17	SP4	YES	APTM100H35FTG
1200	FREDFET 7	350	17	SP3	YES	APTM100H35FT3G
		180	33	SP6	-	APTM100H18FG
	FREDFET 8	800	8	SP1	YES	APTM100H80FT1G
		570	13	SP4	YES	APTM120H57FTG
1200	FREDFET 7	570	13	SP3	YES	APTM120H57FT3G
		290	25	SP6	-	APTM120H29FG
		1400	6	SP1	YES	APTM120H140FT1G



LP8



SP1



SP3

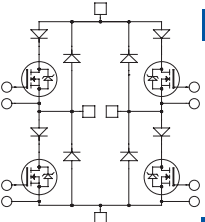


SP4



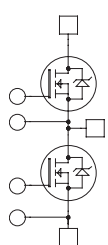
SP6

FULL BRIDGE + SERIES AND PARALLEL DIODES



V _{DSS} (V)	MOSFET TYPE	R _{DS(ON)} m Ohms	I _D (A) T _c =80° C	Package Style	NTC	Part Number
200	MOS 7	20	62	SP4	YES	APTM20HM20STG
500	MOS 7	75	32	SP4	YES	APTM50HM75STG
1000	MOS 7	450	13	SP4	YES	APTM100H45STG

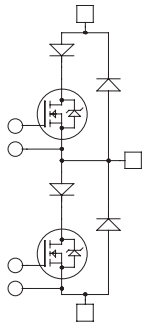
PHASE LEG



V _{DSS} (V)	MOSFET TYPE	R _{DS(ON)} m Ohms	I _D (A) T _c =80° C	Package Style	NTC	Part Number
100	FREDFET 7	4.5	207	SP4	YES	APTM10AM05FTG
		2.25	370	SP6	-	APTM10AM02FG
200	FREDFET 7	10	125	SP4	YES	APTM20AM10FTG
		8	147	SP4	YES	APTM20AM08FTG
		5	250	SP6	-	APTM20AM05FG
		5	250	LP8	YES	APTM20AM05FTG
500	FREDFET 7	4	300	SP6	-	APTM20AM04FG
		38	64	SP4	YES	APTM50AM38FTG
		35	70	SP4	YES	APTM50AM35FTG
	FREDFET 8	25	110	LP8	YES	APTM50AM25FTG
		19	125	SP6	-	APTM50AM19FG
		17	140	SP6	-	APTM50AM17FG
600	COOLMOS	150	19	SP1	YES	APTM50A15UT1G
		70	37	SP1	YES	APTM50AM70UT1G
		24	70	SP1	YES	APTC60AM24T1G
	FREDFET8	35	54	SP1	YES	APTC60AM35T1G
		45	38	SP1	YES	APTC60AM45T1G
		70	29	SP1	YES	APTC60AM70T1G
800	COOLMOS	110	30	SP1	YES	APTM60A11UT1G
		230	15	SP1	YES	APTM60A23UT1G
	FREDFET 7	150	21	SP1	YES	APTC80A15T1G
		180	33	SP4	YES	APTM100A18FTG
1000	FREDFET 7	90	59	SP6	-	APTM100AM90FG
		400	16	SP1	YES	APTM100A40FT1G
	FREDFET 8	460	14	SP1	YES	APTM100A46FT1G
1200	FREDFET 7	290	25	SP4	YES	APTM120A29FTG
		150	45	SP6	-	APTM120A15FG
	FREDFET8	650	12	SP1	YES	APTM120A65FT1G
800	FREDFET8	800	10	SP1	YES	APTM120A80FT1G

MOSFET Power Modules

PHASE LEG + SERIES AND PARALLEL DIODES



V _{DSS} (V)	MOSFET Type	R _{DS(ON)} m Ohms	I _D (A) T _C =80° C	Package Style	NTC	Part Number
200	MOS 7	10	125	SP4	YES	APTM20AM10STG
		6	225	SP6	-	APTM20AM06SG
500	MOS 7	38	64	SP4	YES	APTM50AM38STG
		24	110	SP6	-	APTM50AM24SG
1000	MOS 7	19	125	LP8W	YES	APTM50AM19STG
		230	26	SP4	YES	APTM100A23STG
		130	49	SP6	-	APTM100A13SG
1200	MOS 7	120	50	LP8W	YES	APTM100A12STG
		200	37	SP6	-	APTM120A20SG

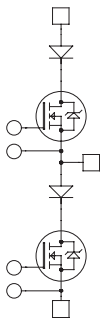


LP8W



SP4

PHASE LEG + SERIES DIODES

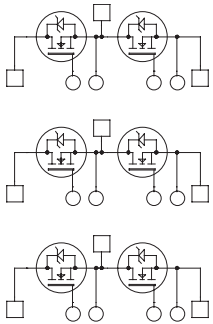


V _{DSS} (V)	MOSFET Type	R _{DS(ON)} m Ohms	I _D (A) T _C =80° C	Package Style	NTC	Part Number
1000	MOS 7	130	49	SP6	-	APTM100A13DG
1200	MOS 7	200	37	SP6	-	APTM120A20DG



SP6

TRIPLE PHASE LEG

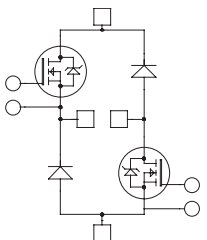


V _{DSS} (V)	MOSFET Type	R _{DS(ON)} m Ohms	I _D (A) T _C =80° C	Package Style	NTC	Part Number
75	MOS 7	4.2	90	SP6-P	-	APTM08TAM04PG
100	FREDFET 7	19	50	SP6-P	-	APTM10TAM19FPG
		9	100	SP6-P	-	APTM10TAM09FPG
200	FREDFET 7	16	74	SP6-P	-	APTM20TAM16FPG
500	FREDFET 7	65	37	SP6-P	-	APTM50TAM65FPG
600	COOLMOS	35	54	SP6-P	-	APTC60TAM35PG
800	COOLMOS	150	21	SP6-P	-	APTC80TA15PG
1000	FREDFET 7	350	17	SP6-P	-	APTM100TA35FPG
1200	FREDFET 7	570	13	SP6-P	-	APTM120TA57FPG



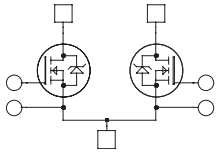
SP6-P

ASYMMETRICAL BRIDGE

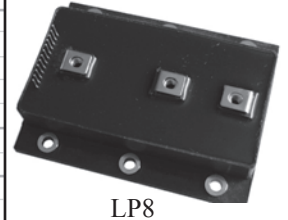


V _{DSS} (V)	MOSFET Type	R _{DS(ON)} m Ohms	I _D (A) T _C =80° C	Package Style	NTC	Part Number
100	MOS 7	4.5	207	SP6	-	APTM10DHM05G
		9	100	SP4	YES	APTM10DHM09TG
200	MOS 7	20	62	SP4	YES	APTM20DHM20TG
		16	74	SP4	YES	APTM20DHM16TG
		10	125	SP6	-	APTM20DHM10G
		8	147	SP6	-	APTM20DHM08G
500	MOS 7	75	32	SP4	YES	APTM50DHM75TG
		65	37	SP4	YES	APTM50DHM65TG
		38	64	SP6	-	APTM50DHM38G
		35	70	SP6	-	APTM50DHM35G

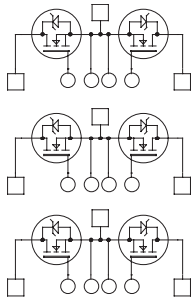
DUAL COMMON SOURCE



V _{DSS} (V)	MOSFET Type	R _{DS(ON)} m Ohms	I _D (A) T _c =80° C	Package Style	NTC	Part Number
100	MOS 7	4.5	207	SP4	YES	APTM10DUM05TG
		2.25	370	SP6	-	APTM10DUM02G
200	MOS 7	10	125	SP4	YES	APTM20DUM10TG
		8	147	SP4	YES	APTM20DUM08TG
		5	250	SP6	-	APTM20DUM05G
		5	250	LP8	YES	APTM20DUM05TG
		4	300	SP6	-	APTM20DUM04G
500	MOS 7	38	64	SP4	YES	APTM50DUM38TG
		35	70	SP4	YES	APTM50DUM35TG
		25	110	LP8	YES	APTM50DUM25TG
		19	125	SP6	-	APTM50DUM19G
		17	140	SP6	-	APTM50DUM17G
1000	MOS 7	180	33	SP4	YES	APTM100DU18TG
		90	59	SP6	-	APTM100DUM90G
1200	MOS 7	290	25	SP4	YES	APTM120DU29TG
		150	45	SP6	-	APTM120DU15G



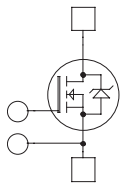
TRIPLE DUAL COMMON SOURCE



V _{DSS} (V)	MOSFET Type	R _{DS(ON)} m Ohms	I _D (A) T _c =80° C	Package Style	NTC	Part Number
75	MOS 7	4.2	90	SP6-P	-	APTM08TDUM04PG
100	MOS 7	19	50	SP6-P	-	APTM10TDUM19PG
		9	100	SP6-P	-	APTM10TDUM09PG
200	MOS 7	16	74	SP6-P	-	APTM20TDUM16PG
500	MOS 7	65	37	SP6-P	-	APTM50TDUM65PG
600	COOLMOS	35	54	SP6-P	-	APTC60TDUM35PG
800	COOLMOS	150	21	SP6-P	-	APTC80TDU15PG
1000	MOS 7	350	17	SP6-P	-	APTM120TDU35PG
1200	MOS 7	570	13	SP6-P	-	APTM120TDU57PG



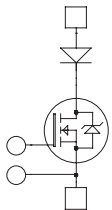
SINGLE SWITCH



V _{DSS} (V)	MOSFET Type	R _{DS(ON)} m Ohms	I _D (A) T _c =80° C	Package Style	NTC	Part Number
100	FREDFET 7	2.25	430	SP6	-	APTM10UM02FAG
		1.50	640	SP6	-	APTM10UM01FAG
200	FREDFET 7	3	434	SP6	-	APTM20UM03FAG
500	FREDFET 7	9	371	SP6	-	APTM50UM09FAG
1000	FREDFET 7	60	97	SP6	-	APTM100UM60FAG
		45	160	SP6	-	APTM100UM45FAG
		95	77	SP6	-	APTM120UM95FAG
1200	FREDFET 7	70	126	SP6	-	APTM120UM70FAG

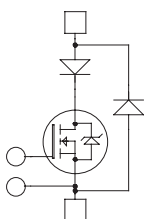


SINGLE SWITCH + SERIES DIODE



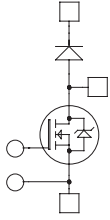
V _{DSS} (V)	MOSFET Type	R _{DS(ON)} m Ohms	I _D (A) T _c =80° C	Package Style	NTC	Part Number
1000	MOS 7	65	110	SP6	-	APTM100UM65DAG
		45	160	SP6	-	APTM100UM45DAG
1200	MOS 7	100	86	SP6	-	APTM120U10DAG
		70	126	SP6	-	APTM120UM70DAG

SINGLE SWITCH + SERIES AND PARALLEL DIODES



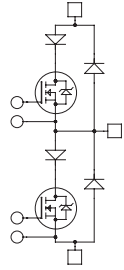
V _{DSS} (V)	MOSFET Type	R _{DS(ON)} m Ohms	I _D (A) T _c =80° C	Package Style	NTC	Part Number
200	MOS 7	9	145	J3	-	APTM20UM09SG
		5	237	J3	-	APTM20UM05SG
		4	310	SP6	-	APTM20UM04SAG
500	MOS 7	25	110	J3	-	APTM50UM25SG
		19	122	J3	-	APTM50UM19SG
1000	MOS 7	13	250	SP6	-	APTM50UM13SAG
		130	48	J3	-	APTM100U13SG
1200	MOS 7	65	100	SP6	-	APTM100UM65SAG
		100	86	SP6	-	APTM120U10SAG

MOSFET Power Modules with SiC Diodes



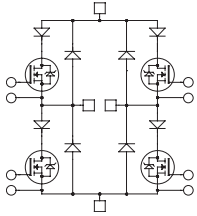
BOOST CHOPPER WITH SiC DIODES

V_{DSS} (V)	MOSFET Type	$R_{DS(ON)}$ m Ohms	I_D (A) $T_c=80^\circ\text{C}$	Package Style	NTC	Part Number
500	MOS 7	38	67	SP4	YES	APTM50DAM38CTG



PHASE LEG + SERIES AND SiC PARALLEL DIODES

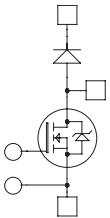
V_{DSS} (V)	MOSFET Type	$R_{DS(ON)}$ m Ohms	I_D (A) $T_c=80^\circ\text{C}$	Package Style	NTC	Part Number
500	MOS 7	38	67	SP4	YES	APTM50AM38SCTG
		24	110	SP6	-	APTM50AM24SCG
1000	MOS 7	230	27	SP4	YES	APTM100A23SCTG
		130	49	SP6	-	APTM100A13SCG



FULL BRIDGE + SERIES AND SiC PARALLEL DIODES

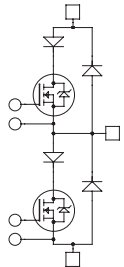
V_{DSS} (V)	MOSFET Type	$R_{DS(ON)}$ m Ohms	I_D (A) $T_c=80^\circ\text{C}$	Package Style	NTC	Part Number
500	MOS 7	75	34	SP4	YES	APTM50HM75SCTG
1000	MOS 7	450	14	SP4	YES	APTM100H45SCTG

COOLMOS™ Power Modules with SiC Diodes



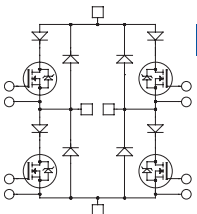
BOOST CHOPPER WITH SiC DIODES

V_{DSS} (V)	MOSFET Type	$R_{DS(ON)}$ m Ohms	I_D (A) $T_c=80^\circ\text{C}$	Package Style	NTC	Part Number
600	COOLMOS	45	38	ISOTOP®	-	APTC50N60JCCU2
		18	107	SP4	YES	APTC60DAM18CTG



PHASE LEG + SERIES AND SiC PARALLEL DIODES

V_{DSS} (V)	MOSFET TYPE	$R_{DS(ON)}$ m Ohms	I_D (A) $T_c=80^\circ\text{C}$	Package Style	NTC	Part Number
600	COOLMOS	35	54	SP4	YES	APTC60AM35SCTG
		18	107	SP6	-	APTC60AM18SCG
		150	21	SP4	YES	APTC80A15SCTG
800	COOLMOS	100	32	SP4	YES	APTC80A10SCTG
		75	43	SP6	-	APTC80AM75SCG



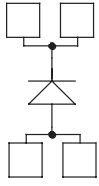
FULL BRIDGE + SERIES AND SiC PARALLEL DIODES

V_{DSS} (V)	MOSFET TYPE	$R_{DS(ON)}$ m Ohms	I_D (A) $T_c=80^\circ\text{C}$	Package Style	NTC	Part Number
600	COOLMOS	70	29	SP4	YES	APTC60HM70SCTG
800	COOLMOS	290	11	SP4	YES	APTC80H29SCTG

“CoolMOS™” comprise a new family of transistors developed by Infineon Technologies AG. “CoolMOS™” is a trademark of Infineon Technologies AG”.

DIODE Power Modules

SINGLE DIODE

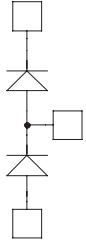


V_{RRM} (V)	FRED Type	IF(A) $T_c=80^\circ\text{C}$	VF(V) $T_j=25^\circ\text{C}$	Package Style	Part Number
200	FRED	500	1.1	LP4	APTDF500U20G
400	FRED	500	1.5	LP4	APTDF500U40G
600	FRED	450	1.8	LP4	APTDF450U60G
1000	FRED	430	2.3	LP4	APTDF430U100G
1200	FRED	400	2.5	LP4	APTDF400U120G



LP4

PHASE LEG

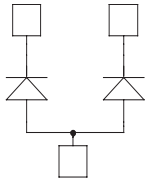


V_{RRM} (V)	FRED Type	IF(A) $T_c=80^\circ\text{C}$	VF(V) $T_j=25^\circ\text{C}$	Package Style	Part Number
200	FRED	400	1.0	SP6	APTDF400AK20G
600	FRED	400	1.6	SP6	APTDF400AK60G
1000	FRED	400	2.1	SP6	APTDF400AK100G
1200	FRED	400	2.4	SP6	APTDF400AK120G
1700	FRED	400	2.2	SP6	APTDF400AK170G



SP1

DUAL COMMON ANODE

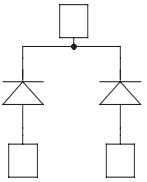


V_{RRM} (V)	FRED Type	IF(A) $T_c=80^\circ\text{C}$	VF(V) $T_j=25^\circ\text{C}$	Package Style	Part Number
200	FRED	400	1.0	SP6	APTDF400AA20G
600	FRED	400	1.6	SP6	APTDF400AA60G
1000	FRED	400	2.1	SP6	APTDF400AA100G
1200	FRED	400	2.4	SP6	APTDF400AA120G
1700	FRED	400	2.2	SP6	APTDF400AA170G



SP4

DUAL COMMON CATHODE

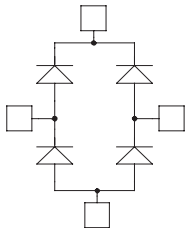


V_{RRM} (V)	FRED Type	IF(A) $T_c=80^\circ\text{C}$	VF(V) $T_j=25^\circ\text{C}$	Package Style	Part Number
200	FRED	400	1.0	SP6	APTDF400KK20G
600	FRED	400	1.6	SP6	APTDF400KK60G
1000	FRED	400	2.1	SP6	APTDF400KK100G
1200	FRED	400	2.4	SP6	APTDF400KK120G
1700	FRED	400	2.2	SP6	APTDF400KK170G



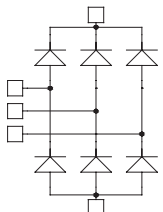
SP6

FULL BRIDGE



V_{RRM} (V)	FRED Type	IF(A) $T_c=80^\circ\text{C}$	VF(V) $T_j=25^\circ\text{C}$	Package Style	Part Number
200	FRED	100	1.0	SP4	APTDF100H20G
		200	1.0	SP6	APTDF200H20G
600	FRED	30	1.8	SP1	APTDF30H601G
		60	1.6	SP1	APTDF60H601G
		100	1.6	SP1	APTDF100H601G
		100	1.6	SP4	APTDF100H60G
		200	1.6	SP6	APTDF200H60G
1000	FRED	100	2.1	SP4	APTDF100H100G
		200	2.1	SP6	APTDF200H100G
1200	FRED	30	2.6	SP1	APTDF30H1201G
		60	2.5	SP1	APTDF60H1201G
		100	2.5	SP1	APTDF100H1201G
		100	2.4	SP4	APTDF100H120G
		200	2.4	SP6	APTDF200H120G
1700	FRED	100	2.2	SP4	APTDF100H170G
		200	2.2	SP6	APTDF200H170G

3-PHASE BRIDGE - RECTIFIER DIODE

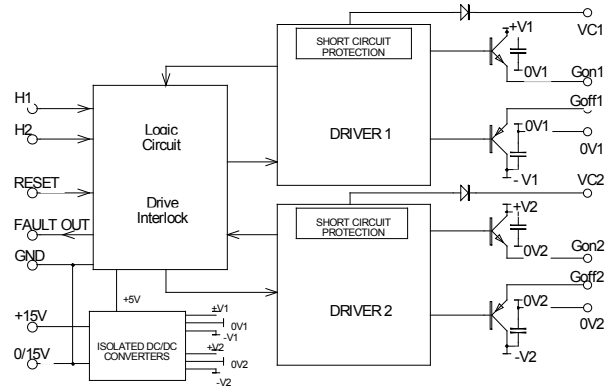


V_{RRM} (V)	FRED Type	IF(A) $T_c=80^\circ\text{C}$	VF(V) $T_j=25^\circ\text{C}$	Package Style	Part Number
1600	Rectifier	40	1.3	SP1	APTDR40X1601G
		70	1.3	SP1	APTDR70X1601G
		90	1.3	SP1	APTDR90X1601G

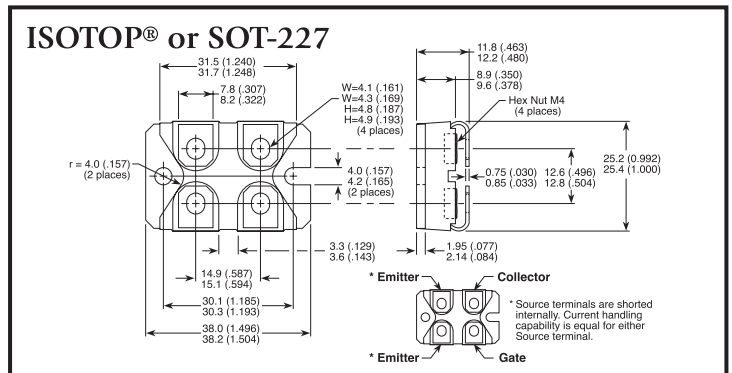
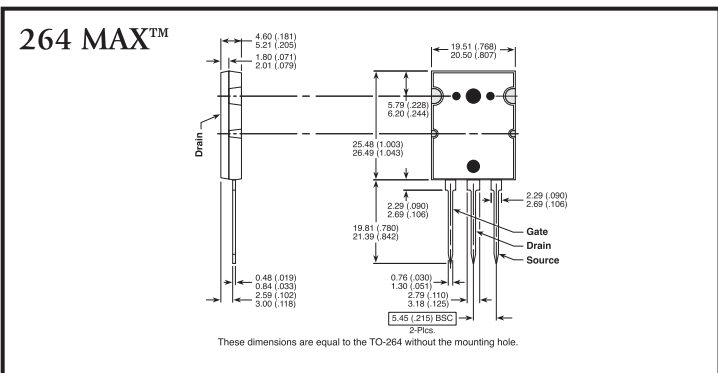
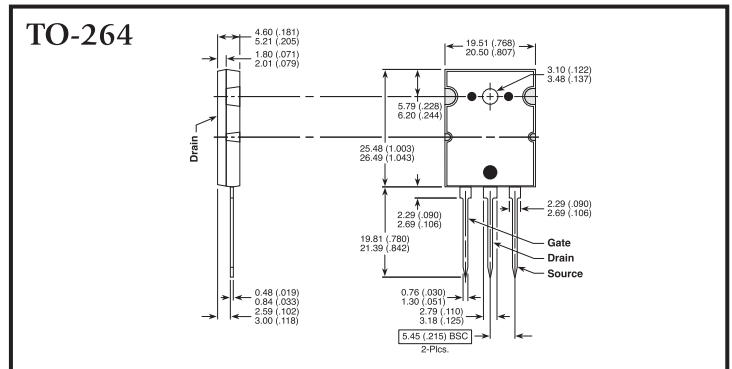
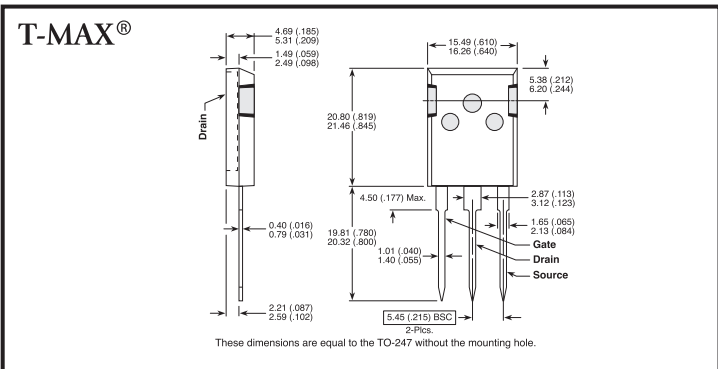
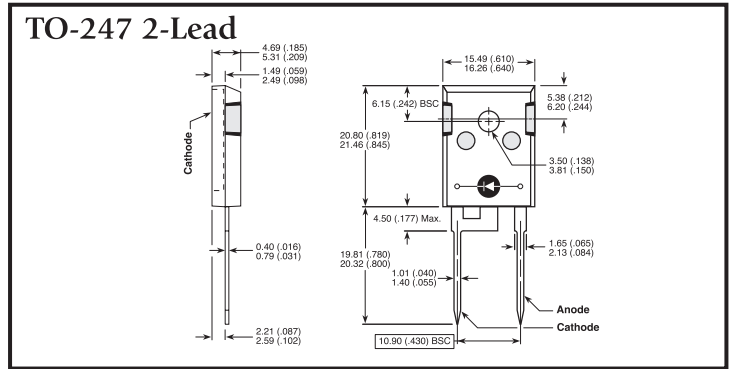
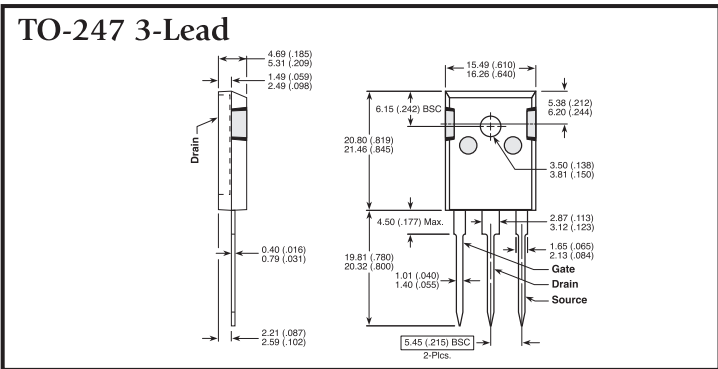
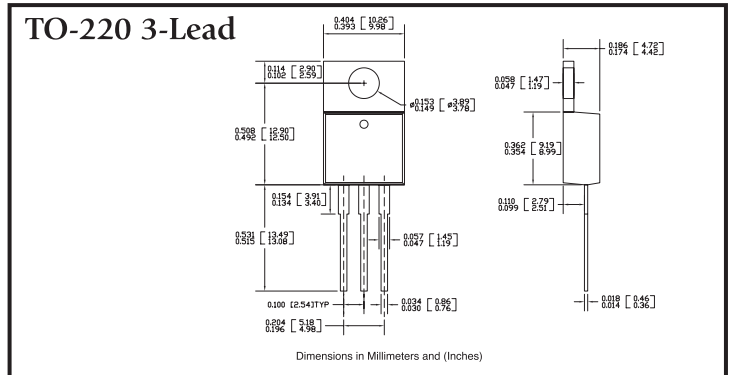
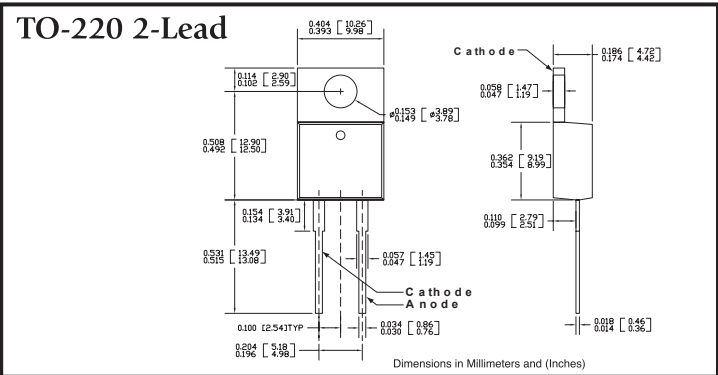
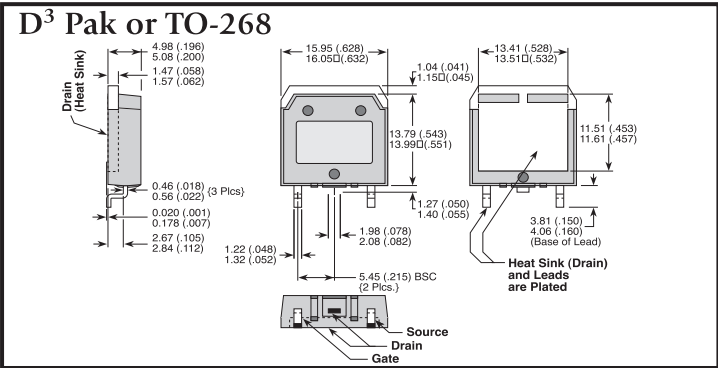
Dual IGBT Isolated Driver

V_{ce} Max (V)	I_{OUT} Peak (A)	Number of Channels	V_{GON}/V_{GOFF}	Input Signal Voltage	Switching Freq. (kHz)	Isolation Voltage (kV)	Part Number
1200	8	2	+15/-6	5	50	2.5	APTRG8A120G

- Driver For Phase Leg IGBT up to 300A/1200V or 600A/600V
- Short Circuit Protection
- Under Voltage Lockout
- Integrated Auxillary Power Supplies
- TTL Compatible Inputs
- Very High EMI Immunity
- Fault and Reset Signals
- RGon and RGoff Externally Selectable
- Dimensions: 50.8mm(H) X 50.8mm(W) X 23.6mm(D)



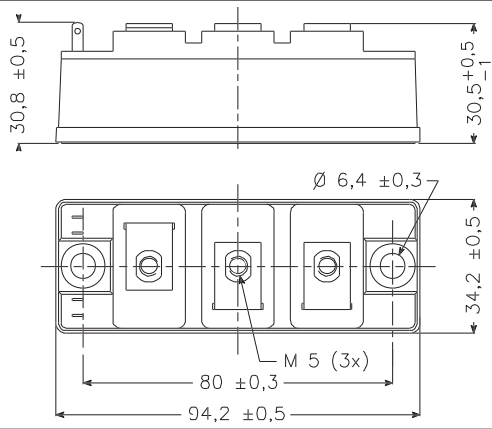
Refer to web page for additional package outline drawings



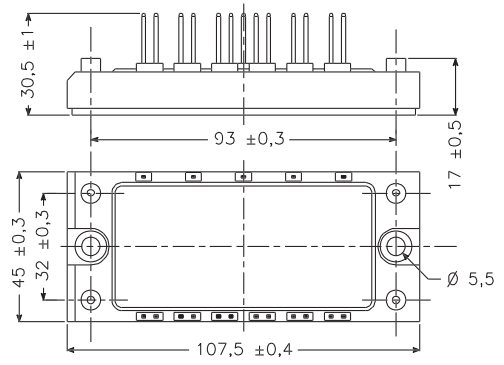
Power Module Outlines

Pin out location depends on the module configuration. Please refer to the product datasheet for pins assignment. All dimensions in millimeter

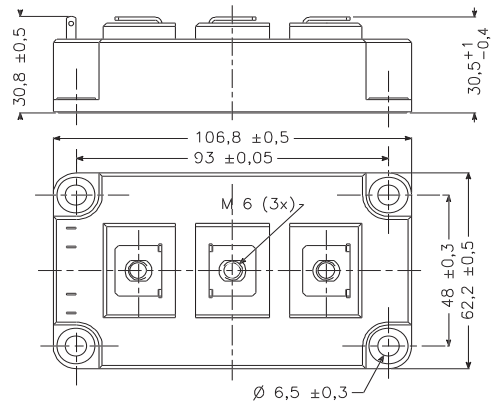
D1



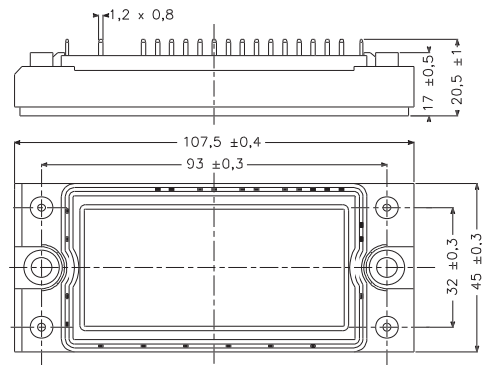
E2



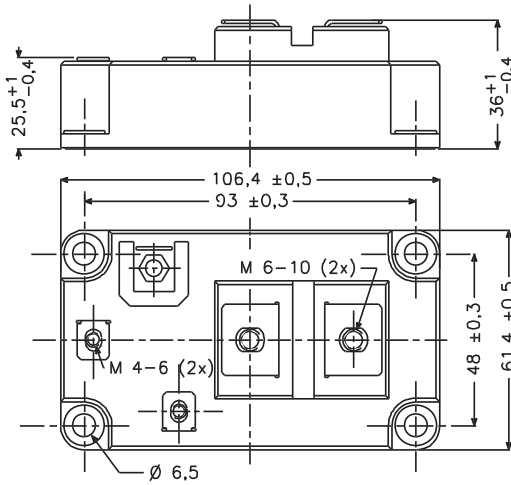
D3



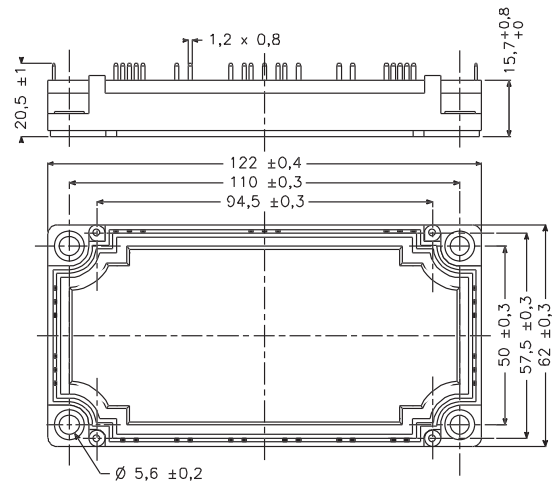
P2



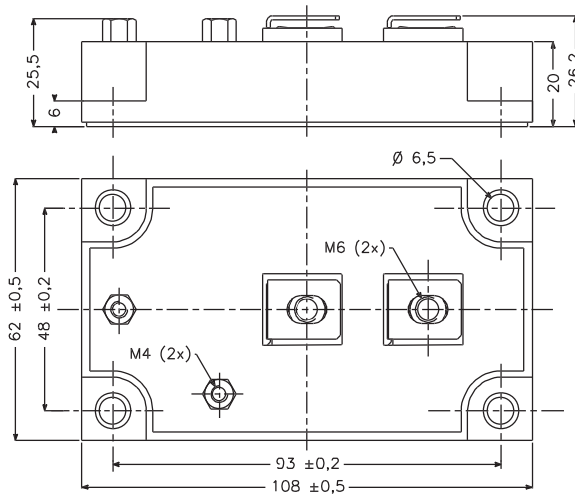
D4



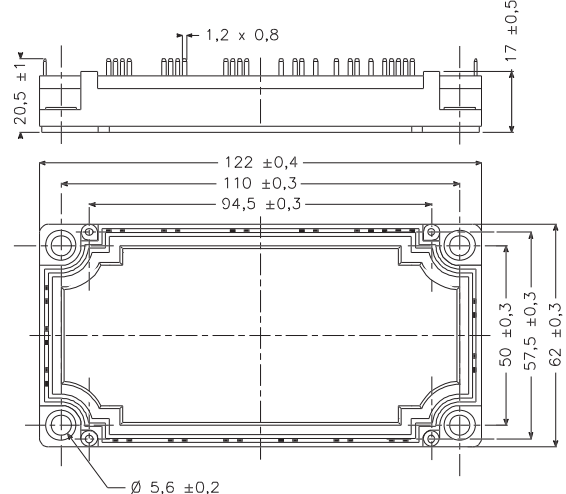
E3

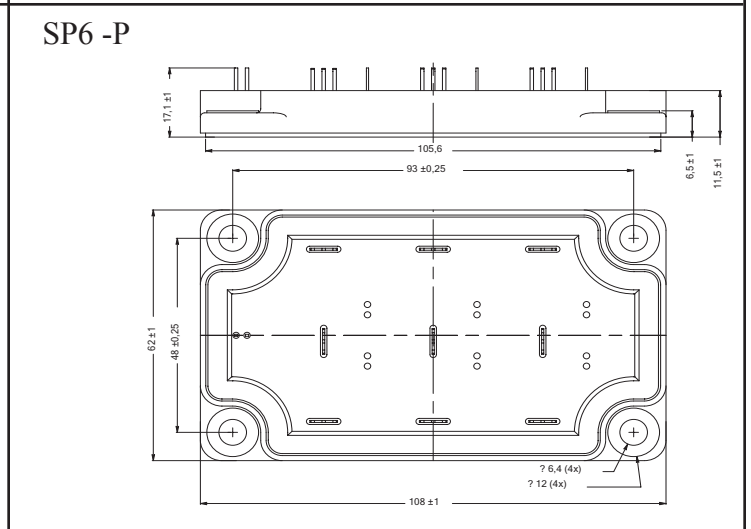
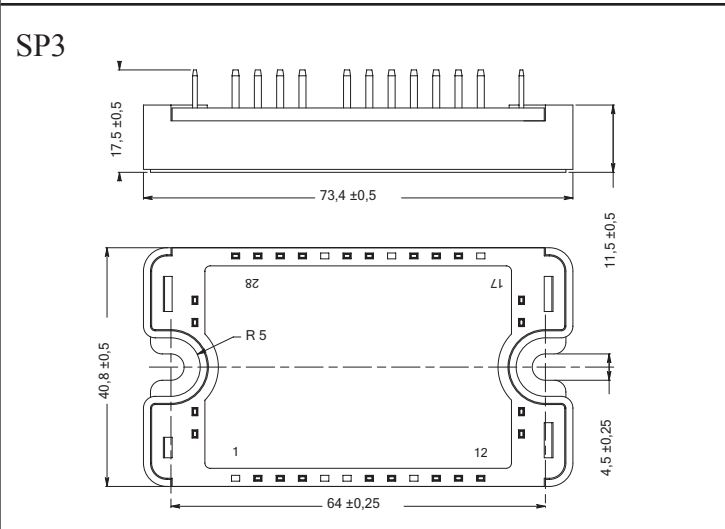
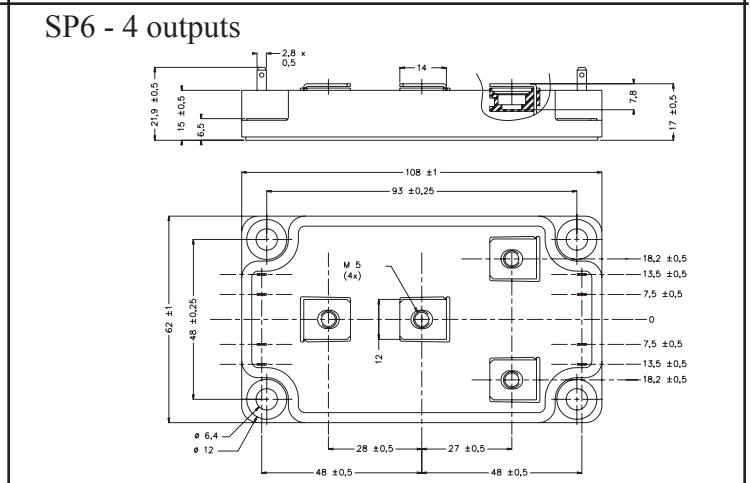
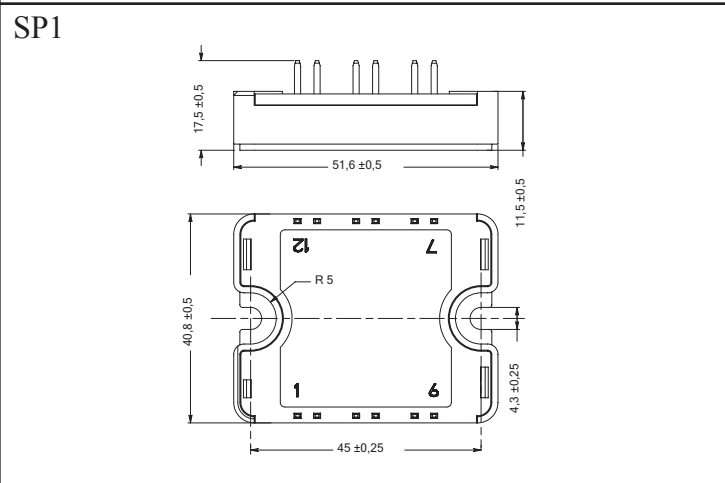
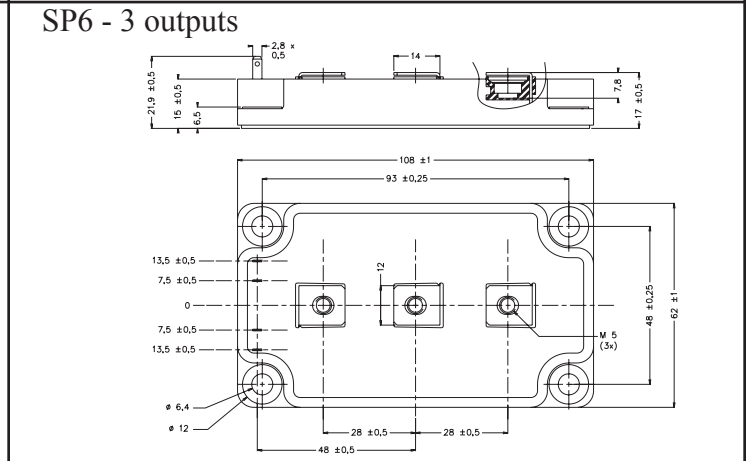
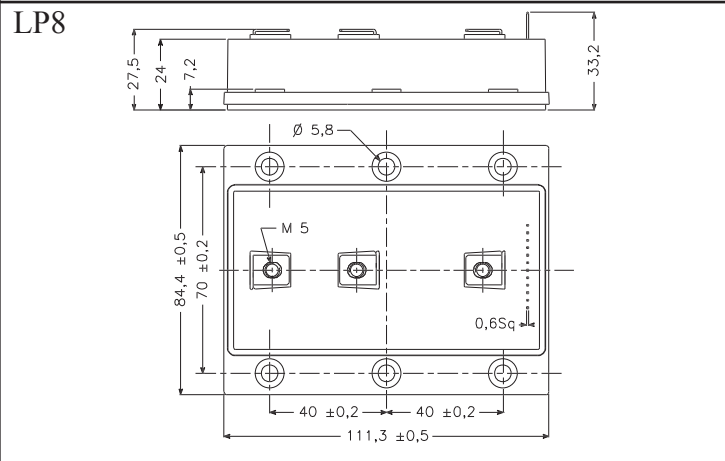
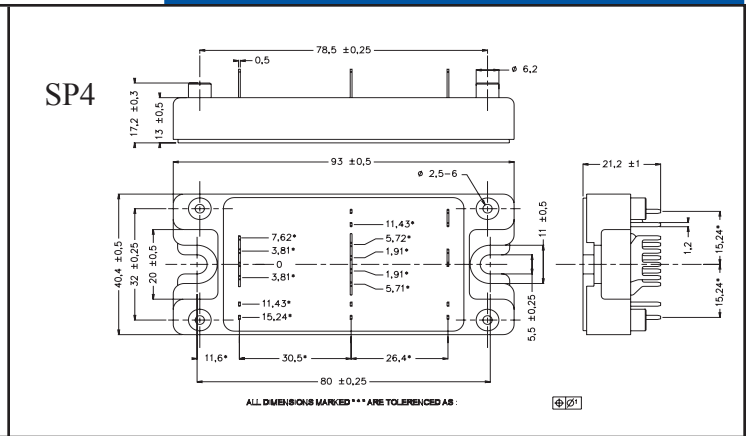
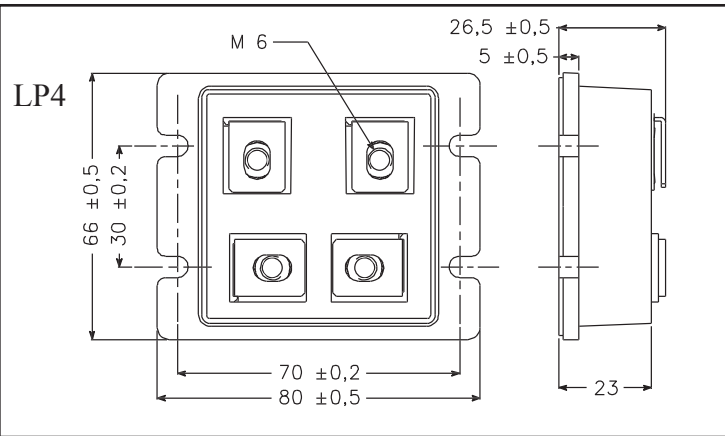


J3



P3







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